

# **bq25898、bq25898D I<sup>2</sup>C 控制单节 4A 快速充电器，采用 MaxCharge™ 技术实现高输入电压和可调节电压 USB On-the-Go 升压模式，**

## 1 特性

- 高效率 4A、1.5MHz 开关模式降压充电器
  - 充电效率高达 92% (3A 充电电流下) 和 91% (4A 充电电流下)
  - 针对高电压输入 (9V/12V) 进行了优化
  - 低功耗 PFM 模式，适用于轻负载操作
- USB On-the-Go (OTG)，可调输出电压范围为 4.5V 至 5.5V
  - 可选 500KHz/1.5MHz 升压转换器，输出电流高达 2.4A
  - 5V、1A 输出电流时升压效率为 94%
  - 精确的断续模式过流保护
- 单个输入，支持 USB 输入和可调高压适配器
  - 支持 3.9V 至 14V 输入电压范围
  - 输入电流限制 (100mA 至 3.25A，分辨率为 50mA)，支持 USB2.0、USB3.0 标准和高压适配器
  - 通过输入电压限制 (最高 14V) 实现最大功率跟踪，适用于各类适配器
  - 自动检测 USB SDP、CDP、DCP 以及非标准适配器 (bq25898)
  - 可编程的 D+/D- 驱动器，用于非标准适配器握手
- 远程电池感测
- 输入电流优化器 (ICO)，无需过载适配器即可最大限度提高输入功率
- 充电器输出与电池终端间的电阻补偿 (IRCOMP)
- 借助 5mΩ 电池放电金属氧化物半导体场效应晶体管 (MOSFET) 实现最高电池放电效率，放电电流高达 9A
- 集成 ADC，用于系统监视 (电压、温度和充电电流)
- 窄 VDC (NVDC) 电源路径管理
  - 与无电池或深度放电电池工作时可瞬时接通
  - 电池管理模式中的理想二极管运行
- BATFET 控制，支持运输模式、唤醒和完全系统复位
- 灵活的自主和 I<sup>2</sup>C 模式，可实现最优系统性能

- 高集成度，包括所有 MOSFET、电流感测和环路补偿
- 12μA 低电池泄漏电流，支持运输模式
- 高精度
  - ±0.5% 充电电压调节
  - ±5% 充电电流调节
  - ±7.5% 输入电流调节
- 安全
  - 用于充电模式和升压模式的电池温度感测
  - 热调节和热关断
- 采用 2.8mm x 2.5mm 42 焊球芯片尺寸球状引脚栅格阵列 (DSBGA) 封装

## 2 应用

- 智能手机
- 平板电脑
- 便携式网络设备

## 3 说明

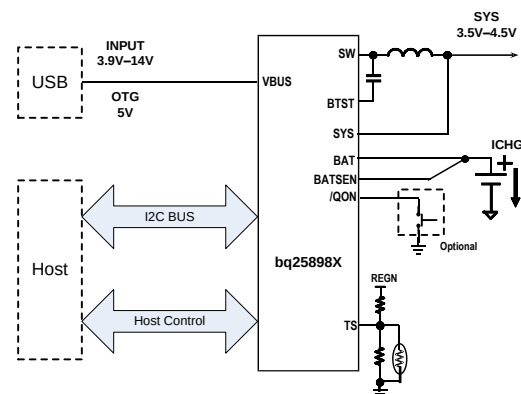
bq25898 和 bq25898D 是适用于锂离子电池和锂聚合物电池的高度集成型 4A 开关模式电池充电管理和系统电源路径管理器件。该器件支持高输入电压快速充电。

器件信息(1)

| 器件型号     | 封装         | 封装尺寸 (标称值)      |
|----------|------------|-----------------|
| bq25898  | DSBGA (42) | 2.80mm x 2.50mm |
| bq25898D | DSBGA (42) | 2.80mm x 2.50mm |

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

简化电路原理图



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## 4 修订历史记录

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| • 已更改 已在特性中将 93% 更改为 94% .....                                                                        | 1    |
| • Changed anode to cathode in BTST .....                                                              | 6    |
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| • Changed falling to rising in $t_{ACOV\_RISING}$ test conditions in Electrical Characteristics ..... | 9    |
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## 5 说明（续）

其低阻抗电源路径对开关模式运行效率进行了优化、缩短了电池充电时间并延长了放电阶段的电池使用寿命。具有充电和系统设置的 I<sup>2</sup>C 串行接口使得此器件成为一个真正的灵活解决方案。

bq25898/98D 是一款适用于单节锂离子电池和锂聚合物电池的高度集成型 4A 开关模式电池充电管理和系统电源路径管理器件。该器件支持高输入电压快速充电，适用于各类智能手机、平板电脑和便携式设备。其低阻抗电源路径对开关模式运行效率进行了优化、缩短了电池充电时间并延长了放电阶段的电池使用寿命。该器件还集成了输入电流优化器 (ICO) 和电阻补偿 (IRCOMP)，从而为电池提供最大充电功率。该解决方案在系统和电池之间高度集成输入反向阻断场效应晶体管 (FET) (RBFET, Q1)、高侧开关 FET (HSFET, Q2)、低侧开关 FET (LSFET, Q3) 以及电池 FET (BATFET, Q4)。它还集成了自举二极管以进行高侧栅极驱动和电池监视，从而简化系统设计。具有充电和系统设置的 I<sup>2</sup>C 串行接口使得此器件成为一个真正的灵活解决方案。

该器件支持多种输入源，包括标准 USB 主机端口、USB 充电端口以及兼容 USB 的可调节高电压适配器。为支持通过可调节高电压适配器进行快速充电，bq25898D 提供了 MaxCharge™ 握手支持（使用 D+/D- 引脚和 DSEL 引脚）以进行 USB 开关控制。此外，bq25898D 和 bq25898 还提供有相应的接口，以支持采用输入电流脉冲协议的可调节高电压适配器。为了设定默认输入电流限值，器件使用内置 USB 接口 (bq25898D) 或者从系统检测电路（如 USB PHY 器件）(bq25898) 中获取结果。该器件符合 USB 2.0 和 USB 3.0 电源规范，具有输入电流和电压调节功能。此外，输入电流优化器 (ICO) 还能够检测输入源未发生过载时的最大功率点。该器件还具有高达 2.4A 的限流能力，能够为 VBUS 提供 5V（4.5V-5.5V 可调节）电压，符合 USB On-the-Go (OTG) 运行功率额定值规范。

电源路径管理将系统电压调节为稍稍高于电池电压，但是又不会下降到低于 3.5V 最小系统电压（可编程）。借助于这个特性，即使在电池电量完全耗尽或者电池被拆除时，系统也能保持运行。当达到输入电流限值或电压限值时，电源路径管理自动将充电电流减少为 0。随着系统负载持续增加，电源路径在满足系统电源需求之前将电池放电。这种工作方式可防止输入源发生过载。

此器件在无需软件控制情况下启动并完成一个充电周期。它自动检测电池电压并通过三个阶段为电池充电：预充电、恒定电流和恒定电压。在充电周期的末尾，当充电电流低于在恒定电压阶段中预设定的限值时，充电器自动终止。当整个电池下降到低于再充电阈值时，充电器将自动启动另外一个充电周期。

此充电器提供针对电池充电和系统运行的多种安全特性，其中包括电池负温度系数热敏电阻监视、充电安全定时器和过压/过流保护。当结温超过 120°C（可设定）时，热调节减少充电电流。STAT 输出报告充电状态和任何故障条件。PG 输出 (bq25898) 指示电源是否正常。当故障发生时，INT 会立即通知主机。

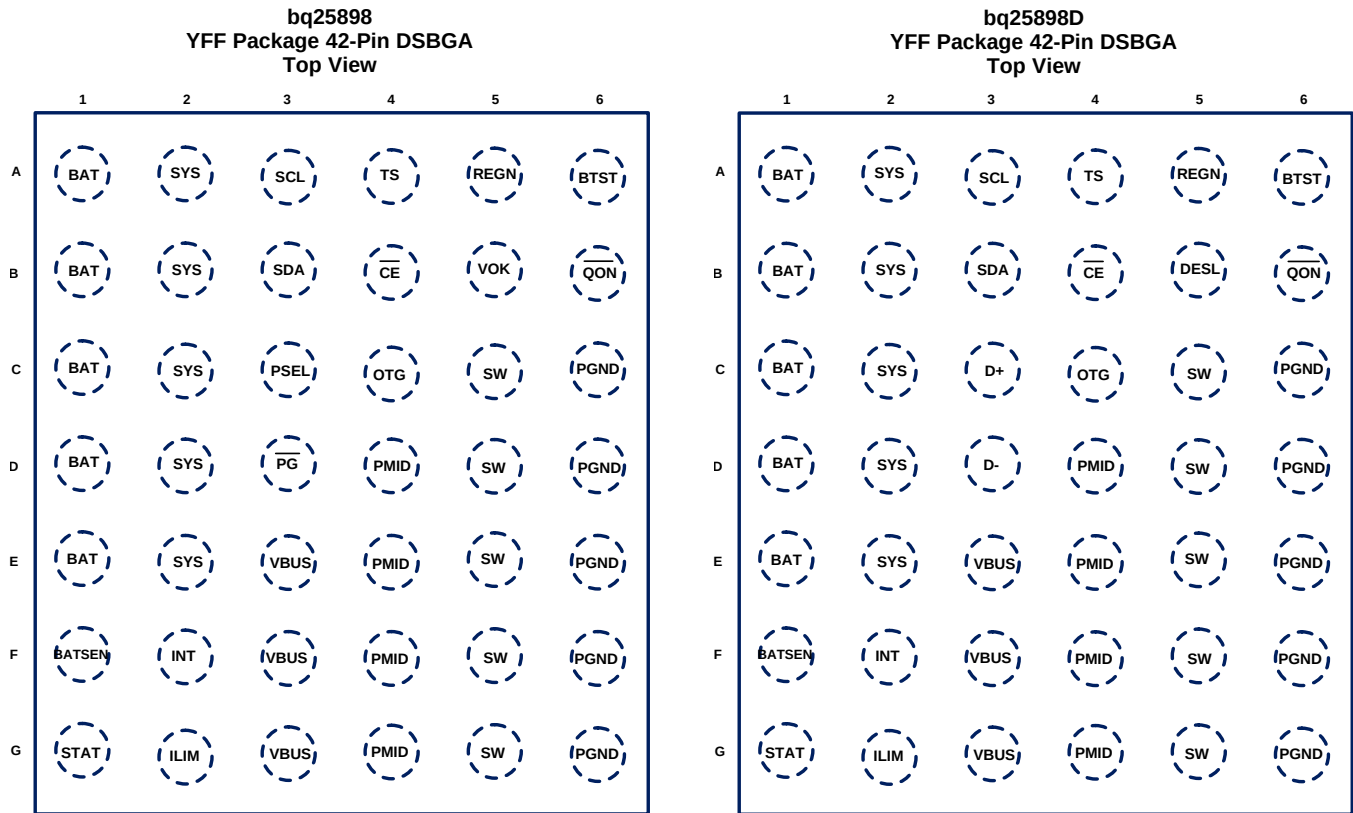
该器件还提供了一个 7 位模数转换器 (ADC)，用于监视充电电流和输入/电池/系统 (VBUS、BAT、SYS、TS) 电压。QON 引脚提供 BATFET 使能/复位控制，以使器件退出低功耗出厂模式或完全系统复位功能。

这些器件采用 42 焊球、2.8 mm x 2.5mm DSBGA 封装。

## 6 Device Comparison Table

|                                   | <b>bq25898D</b>                    | <b>bq25898</b>                     |
|-----------------------------------|------------------------------------|------------------------------------|
| I <sup>2</sup> C Address          | 6AH (1101010B + R $\overline{W}$ ) | 6BH (1101011B + R $\overline{W}$ ) |
| Charge Mode Frequency             | 1.5 MHz                            | 1.5 MHz                            |
| Boost Mode Frequency              | 1.5 MHz (default) / 500 KHz        | 1.5 MHz (default) / 500 KHz        |
| USB Detection                     | D+/D–                              | PSEL/OTG                           |
| VBUS Overvoltage                  | 14.0 V                             | 14.0 V                             |
| REGN LDO                          | 6 V                                | 6 V                                |
| Default Adapter Current Limit     | 3.25 A                             | 3.25 A                             |
| Default Battery Charge Voltage    | 4.208 V                            | 4.208 V                            |
| Maximum Charge Current            | 4.032 A                            | 4.032 A                            |
| Default Charge Current            | 2.048 A                            | 2.048 A                            |
| Default Pre-charge Current        | 128 mA                             | 128 mA                             |
| Maximum Pre-charge Current        | 1.024 A                            | 1.024A                             |
| Maximum Boost Mode Output Current | 2.4A                               | 2.4A                               |
| Charging Temperature Profile      | JEITA                              | JEITA                              |
| Status Output                     | STAT                               | STAT, $\overline{PG}$              |

## 7 Pin Configuration and Functions



### Pin Functions

| PIN                    |         |          | TYPE <sup>(1)</sup> | DESCRIPTION                                                                                                                                                                                                                                                                                                                           |
|------------------------|---------|----------|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                   | bq25898 | bq25898D |                     |                                                                                                                                                                                                                                                                                                                                       |
| VBUS                   | E3-G3   | E3-G3    | P                   | Charger Input Voltage. The internal n-channel reverse block MOSFET (RBFET) is connected between VBUS and PMID with VBUS on source. Place a 1-μF ceramic capacitor from VBUS to PGND and place it as close as possible to IC.                                                                                                          |
| D+                     | –       | C3       | AIO                 | Positive line of the USB data line pair. D+/D- based USB host/charging port detection. The detection includes data contact detection (DCD), primary and secondary detection in BC1.2, and Adjustable high voltage adapter.                                                                                                            |
| PSEL                   | C3      | –        | DI                  | Power source selection input. High indicates a USB host source and Low indicates an adapter source.                                                                                                                                                                                                                                   |
| D–                     | –       | D3       | AIO                 | Negative line of the USB data line pair. D+/D- based USB host/charging port detection. The detection includes data contact detection (DCD), primary and secondary detection in BC1.2, and Adjustable high voltage adapter.                                                                                                            |
| $\overline{\text{PG}}$ | D3      | –        | DO                  | Open drain active low power good indicator. Connect to the pull up rail via 10-kΩ resistor. LOW indicates a good input source if the input voltage is within $V_{\text{VBUS\_OP}}$ , above SLEEP mode threshold ( $V_{\text{SLEEP2}}$ ), and current limit is above $I_{\text{BATSRC}}(30 \text{ mA})$ .                              |
| STAT                   | G1      | G1       | DO                  | Open drain charge status output to indicate various charger operation. Connect to the pull up rail via 10-kΩ resistor. LOW indicates charge in progress. HIGH indicates charge complete or charge disabled. When any fault condition occurs, STAT pin blinks in 1 Hz. The STAT pin function can be disabled when STAT_DIS bit is set. |
| SCL                    | A3      | A3       | DI                  | I2C Interface clock. Connect SCL to the logic rail through a 10-kΩ resistor.                                                                                                                                                                                                                                                          |
| SDA                    | B3      | B3       | DIO                 | I2C Interface data. Connect SDA to the logic rail through a 10-kΩ resistor.                                                                                                                                                                                                                                                           |
| INT                    | F2      | F2       | DO                  | Open-drain Interrupt Output. Connect the INT to a logic rail via 10-kΩ resistor. The INT pin sends active low, 256-μs pulse to host to report charger device status and fault.                                                                                                                                                        |
| OTG                    | C4      | C4       | DI                  | Active high enable pin during boost mode. Deleted text from the OTG pin Description "OTG = High, IINLIM is set to USB500 mode". The boost mode is activated when OTG_CONFIG = 1 and OTG pin is high.Changed the Description of the OTG pin in the Pin Functions table.                                                                |

(1) DI (Digital Input), DO (Digital Output), DIO (Digital Input/Output), AI (Analog Input), AO (Analog Output), AIO (Analog Input/Output)

### Pin Functions (continued)

| PIN                     |         |          | TYPE <sup>(1)</sup> | DESCRIPTION                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|-------------------------|---------|----------|---------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                    | bq25898 | bq25898D |                     |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| $\overline{\text{CE}}$  | B4      | B4       | DI                  | Active low Charge Enable pin. Battery charging is enabled when CHG_CONFIG = 1 and CE pin = Low. CE pin must be pulled High or Low.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| ILIM                    | G2      | G2       | AI                  | Input current limit Input. ILIM pin sets the maximum input current and can be used to monitor input current. ILIM pin sets the maximum input current limit by regulating the ILIM voltage at 0.8 V. A resistor is connected from ILIM pin to ground to set the maximum limit as $I_{INMAX} = K_{ILIM}/R_{ILIM}$ . The actual input current limit is the lower limit set by ILIM pin (when EN_ILIM bit is high) or IILIM register bits. Input current limit of less than 500 mA is not support on ILIM pin. ILIM pin can also be used to monitor input current when the voltage is below 0.8V. The input current is proportional to the voltage on ILIM pin and can be calculated by $I_{IN} = (K_{ILIM} \times V_{ILIM}) / (R_{ILIM} \times 0.8)$ . The ILIM pin function can be disabled when EN_ILIM bit is 0. |
| TS                      | A4      | A4       | AI                  | Temperature qualification voltage input. Connect a negative temperature coefficient thermistor. Program temperature window with a resistor divider from REGN to TS to GND. Charge suspends when either TS pin is out of range. Recommend 103AT-2 thermistor.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| $\overline{\text{QON}}$ | B6      | B6       | DI                  | BATFET enable/reset control input. When BATFET is in ship mode, a logic low of $t_{SHIPMODE}$ (typical 1sec) duration turns on BATFET to exit shipping mode. . When VBUS is not plugged-in, a logic low of $t_{QON\_RST}$ (typical 19.5sec) duration resets SYS (system power) by turning BATFET off for $t_{BATFET\_RST}$ (typical 0.325sec) and then re-enable BATFET to provide full system power reset. The pin contains an internal pull-up to maintain default high logic                                                                                                                                                                                                                                                                                                                                  |
| BAT                     | A1-E1   | A1-E1    | P                   | Battery connection point to the positive terminal of the battery pack. The internal BATFET is connected between BAT and SYS. Connect a 10uF closely to the BAT pin.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| SYS                     | A2-E2   | A2-E2    | P                   | System connection point. The internal BATFET is connected between BAT and SYS. When the battery falls below the minimum system voltage, switch-mode converter keeps SYS above the minimum system voltage. Connect a 20uF closely to the SYS pin.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| PGND                    | C6-G6   | C6-G6    | P                   | Power ground connection for high-current power converter node.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| SW                      | C5-G5   | C5-G5    | P                   | Switching node connecting to output inductor. Internally SW is connected to the source of the n-channel HSFET and the drain of the n-channel LSFET. Connect the 0.047μF bootstrap capacitor from SW to BTST.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| BTST                    | A6      | A6       | P                   | PWM high side driver positive supply. Internally, the BTST is connected to the cathode of the boost-strap diode. Connect the 0.047μF bootstrap capacitor from SW to BTST.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| REGN                    | A5      | A5       | P                   | PWM low side driver positive supply output. Internally, REGN is connected to the anode of the boost-strap diode. Connect a 4.7 μF (10 V rating) ceramic capacitor from REGN to analog GND. The capacitor should be placed close to the IC. REGN also serves as bias rail of TS pin.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| PMID                    | D4-G44  | D4-G4    | DO                  | Connected to the drain of the reverse blocking MOSFET (RBFET) and the drain of HSFET. Given the total input capacitance, put 1μF on VBUS to PGND, and the rest capacitance on PMID to PGND.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| DSEL                    | –       | B5       | DO                  | Active high D+/D- multiplexer selection control. Connect a 47-nF (6V rating) ceramic capacitor from DSEL to analog GND. The pin is normally low. During input source type detection, the pin drives high to indicate the bq25890 D+/D- detection is in progress and needs to take control of D+, D- signals. When detection is completed, the pin keeps high when DCP, MaxCharge or HVDCP is detected. The pin returns to low when other input source type is detected                                                                                                                                                                                                                                                                                                                                           |
| VOK                     | B5      | –        | DO                  | LDO output to driver USB PHY/MUX. Connect a 47nF ceramic capacitor from VOK to analog GND.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
| BATSEN                  | F1      | F1       | AI                  | Remote battery sense input. The typical pin resistance is 800 kΩ. Connect as close to battery as possible.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |

## 8 Specifications

### 8.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                                             |                                                                                | MIN  | MAX | VALUE |
|---------------------------------------------|--------------------------------------------------------------------------------|------|-----|-------|
| Voltage range (with respect to GND)         | VBUS (converter not switching)                                                 | –2   | 22  | V     |
|                                             | PMID (converter not switching)                                                 | –0.3 | 22  | V     |
|                                             | STAT                                                                           | –0.3 | 20  | V     |
|                                             | $\overline{\text{PG}}$ (bq25898)                                               | –0.3 | 7   | V     |
|                                             | PSEL (bq25898)                                                                 | –0.3 | 7   | V     |
|                                             | VOK (bq25898)                                                                  | –0.3 | 7   | V     |
|                                             | DSEL (bq25898D)                                                                | –0.3 | 7   | V     |
|                                             | D+, D– (bq25898D)                                                              | –0.3 | 7   | V     |
|                                             | BTST                                                                           | –0.3 | 20  | V     |
|                                             | SW                                                                             | –3   | 16  | V     |
|                                             | BAT, SYS (converter not switching)                                             | –0.3 | 6   | V     |
|                                             | SDA, SCL, INT, OTG, REGN, TS, $\overline{\text{CE}}$ , $\overline{\text{QON}}$ | –0.3 | 7   | V     |
|                                             | BTST TO SW                                                                     | –0.3 | 7   | V     |
|                                             | PGND to GND                                                                    | –0.3 | 0.3 | V     |
|                                             | BATSEN                                                                         | –0.3 | 7   | V     |
|                                             | ILIM                                                                           | –0.3 | 5   | V     |
| Output sink current                         | INT, STAT                                                                      |      | 6   | mA    |
|                                             | $\overline{\text{PG}}$ (bq25898)                                               |      | 6   | mA    |
|                                             | DSEL (bq25898D)                                                                |      | 5   | mA    |
|                                             | VOK (bq25898)                                                                  |      | 5   | mA    |
| Junction temperature                        |                                                                                | –40  | 150 | °C    |
| Storage temperature range, T <sub>stg</sub> |                                                                                | –65  | 150 | °C    |

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.

### 8.2 ESD Ratings

|                  |                         |                                                                                | VALUE | UNIT |
|------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>ESD</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                  |                         | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±250  | V    |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### 8.3 Recommended Operating Conditions

|           |                                          | MIN | MAX                                | UNIT |
|-----------|------------------------------------------|-----|------------------------------------|------|
| $V_{IN}$  | Input voltage                            | 3.9 | 14 <sup>(1)</sup>                  | V    |
| $I_{IN}$  | Input current (VBUS)                     |     | 3.25                               | A    |
| $I_{SYS}$ | Output current (SW)                      |     | 4                                  | A    |
| $V_{BAT}$ | Battery voltage                          |     | 4.608                              | V    |
| $I_{BAT}$ | Fast charging current                    |     | 4                                  | A    |
|           | Discharging current with internal MOSFET |     | Up to 6 (continuous)               | A    |
|           |                                          |     | 9 (peak)<br>(Up to 1 sec duration) | A    |
| $T_A$     | Operating free-air temperature range     | –40 | 85                                 | °C   |

- (1) The inherent switching noise voltage spikes should not exceed the absolute maximum rating on either the BTST or SW pins. A tight layout minimizes switching noise.

### 8.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | bq25898,<br>bq25898D | UNIT |
|-------------------------------|----------------------------------------------|----------------------|------|
|                               |                                              | YFF (DSBGA)          |      |
|                               |                                              | 42-BALL              |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 53.5                 | °C/W |
| $R_{\theta JCTop}$            | Junction-to-case (top) thermal resistance    | 0.2                  | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 8.2                  | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 0.9                  | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 8.2                  | °C/W |
| $R_{\theta JCBot}$            | Junction-to-case (bottom) thermal resistance | N/A                  | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 8.5 Electrical Characteristics

$V_{VBUS\_UVLOZ} < V_{VBUS} < V_{ACOV}$  and  $V_{VBUS} > V_{BAT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                 | TEST CONDITIONS                                                      | MIN                                                                                                                   | TYP | MAX | UNIT          |
|---------------------------|----------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|-----|-----|---------------|
| <b>QUIESCENT CURRENTS</b> |                                                                      |                                                                                                                       |     |     |               |
| $I_{BAT}$                 | Battery discharge current (BAT, SW, SYS) in buck mode                | $V_{BAT} = 4.2\text{ V}$ , $V_{(VBUS)} < V_{(UVLO)}$ , leakage between BAT and VBUS                                   |     | 5   | $\mu\text{A}$ |
|                           |                                                                      | High-Z Mode, No VBUS, BATFET Disabled (REG09[5] = 1), Battery Monitor Disabled, $T_J < 85^{\circ}\text{C}$            | 12  | 23  | $\mu\text{A}$ |
|                           |                                                                      | High-Z Mode, No VBUS, BATFET Enabled (REG09[5] = 0), Battery Monitor Disabled, $T_J < 85^{\circ}\text{C}$             | 32  | 60  | $\mu\text{A}$ |
| $I_{(VBUS\_HIZ)}$         | Input supply current (VBUS) in buck mode when High-Z mode is enabled | $V_{(VBUS)} = 5\text{ V}$ , High-Z Mode, No Battery, Battery Monitor Disabled                                         | 15  | 35  | $\mu\text{A}$ |
|                           |                                                                      | $V_{(VBUS)} = 12\text{ V}$ , High-Z Mode, No Battery, Battery Monitor Disabled                                        | 25  | 50  | $\mu\text{A}$ |
| $I_{(VBUS)}$              | Input supply current ( $V_{BUS}$ ) in buck mode                      | $V_{BUS} > V_{(UVLO)}$ , $V_{BUS} > V_{BAT}$ , Converter not switching                                                | 1.5 | 3   | mA            |
|                           |                                                                      | $V_{BUS} > V_{(UVLO)}$ , $V_{BUS} > V_{BAT}$ , Converter switching, $V_{BAT} = 3.2\text{ V}$ , $I_{SYS} = 0\text{ A}$ | 3   |     | mA            |
|                           |                                                                      | $V_{BUS} > V_{(UVLO)}$ , $V_{BUS} > V_{BAT}$ , Converter switching, $V_{BAT} = 3.8\text{ V}$ , $I_{SYS} = 0\text{ A}$ | 3   |     | mA            |
| $I_{(BOOST)}$             | Battery discharge current in boost mode                              | $V_{BAT} = 4.2\text{ V}$ , Boost mode, $I_{(VBUS)} = 0\text{ A}$ , Converter switching                                | 5   |     | mA            |
| <b>VBUS/BAT POWER UP</b>  |                                                                      |                                                                                                                       |     |     |               |
| $V_{(VBUS\_OP)}$          | VBUS operating range                                                 | 3.9                                                                                                                   |     | 14  | V             |
| $V_{(VBUS\_UVLOZ)}$       | VBUS for active $I^2\text{C}$ , no battery                           | 3.6                                                                                                                   |     |     | V             |
| $V_{(SLEEP)}$             | Sleep mode falling threshold                                         | 25                                                                                                                    | 65  | 120 | mV            |
| $V_{(SLEEP2)}$            | Sleep mode rising threshold                                          | 130                                                                                                                   | 250 | 370 | mV            |



## Electrical Characteristics (continued)

$V_{VBUS\_UVLOZ} < V_{VBUS} < V_{ACOV}$  and  $V_{VBUS} > V_{BAT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                    |                                                                         | TEST CONDITIONS                                                                                                                                          | MIN   | TYP                            | MAX   | UNIT          |
|------------------------------|-------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|-------|--------------------------------|-------|---------------|
| $V_{(ACOV)}$                 | VBUS over-voltage rising threshold                                      |                                                                                                                                                          | 13.9  |                                | 14.6  | V             |
|                              | VBUS over-voltage falling threshold                                     |                                                                                                                                                          | 13.3  |                                | 13.9  | V             |
| $t_{ACOV\_RISING}$           | ACOV rising deglitch                                                    | $V_{VBUS}$ rising                                                                                                                                        |       | 1                              |       | $\mu\text{s}$ |
| $t_{ACOV\_FALLING}$          | ACOV falling deglitch                                                   | $V_{VBUS}$ falling                                                                                                                                       |       | 1                              |       | ms            |
| $V_{BAT(UVLOZ)}$             | Battery for active $I^2\text{C}$ , no VBUS                              |                                                                                                                                                          | 2.3   |                                |       | V             |
| $V_{BAT(DPL)}$               | Battery depletion falling threshold                                     |                                                                                                                                                          | 2.15  |                                | 2.5   | V             |
| $V_{BAT(DPLZ)}$              | Battery depletion rising threshold                                      |                                                                                                                                                          | 2.35  |                                | 2.7   | V             |
| $V_{(VBUSMIN)}$              | Bad adapter detection threshold                                         |                                                                                                                                                          |       | 3.8                            |       | V             |
| $I_{(BADSRC)}$               | Bad adapter detection current source                                    |                                                                                                                                                          |       | 30                             |       | mA            |
| <b>POWER-PATH MANAGEMENT</b> |                                                                         |                                                                                                                                                          |       |                                |       |               |
| $V_{SYS}$                    | Typical system regulation voltage                                       | $I_{(SYS)} = 0\text{ A}$ , $V_{BAT} > V_{SYS(MIN)}$ , BATFET Disabled (REG09[5]=1)                                                                       |       | $V_{BAT} + 50\text{ mV}$       |       | V             |
|                              |                                                                         | $I_{SYS} = 0\text{ A}$ , $V_{BAT} < V_{SYS(MIN)}$ , BATFET Disabled (REG09[5]=1)                                                                         |       | $V_{SYS(MIN)} + 250\text{ mV}$ |       | V             |
| $V_{SYS(MIN)}$               | Minimum DC system voltage output                                        | $V_{BAT} < V_{SYS(MIN)}$ , $SYS\_MIN = 3.5\text{ V}$ (REG03[3:1] = 101), $I_{SYS} = 0\text{ A}$                                                          | 3.60  | 3.75                           |       | V             |
| $V_{SYS(MAX)}$               | Maximum DC system voltage output                                        | $V_{BAT} = 4.35\text{ V}$ , $SYS\_MIN = 3.5\text{ V}$ (REG03[3:1] = 101), $I_{SYS} = 0\text{ A}$                                                         |       | 4.40                           | 4.42  | V             |
| $R_{ON(RBFET)}$              | Top reverse blocking MOSFET (RBFET) on-resistance between VBUS and PMID | $T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$                                                                                                         |       | 28                             | 40    | m $\Omega$    |
|                              |                                                                         | $T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$                                                                                                        |       | 28                             | 47    | m $\Omega$    |
| $R_{ON(HSFET)}$              | Top switching MOSFET (HSFET) on-resistance between PMID and SW          | $T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$                                                                                                         |       | 24                             | 33    | m $\Omega$    |
|                              |                                                                         | $T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$                                                                                                        |       | 24                             | 40    | m $\Omega$    |
| $R_{ON(LSFET)}$              | Bottom switching MOSFET (LSFET) on-resistance between SW and GND        | $T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$                                                                                                         |       | 12                             | 18    | m $\Omega$    |
|                              |                                                                         | $T_J = -40^{\circ}\text{C} - 125^{\circ}\text{C}$                                                                                                        |       | 12                             | 21    | m $\Omega$    |
| $V_{(FWD)}$                  | BATFET forward voltage in supplement mode                               | BAT discharge current 10 mA                                                                                                                              |       | 30                             |       | mV            |
| <b>BATTERY CHARGER</b>       |                                                                         |                                                                                                                                                          |       |                                |       |               |
| $V_{BAT(REG\_RANGE)}$        | Typical charge voltage range                                            |                                                                                                                                                          | 3.840 |                                | 4.608 | V             |
| $V_{BAT(REG\_STEP)}$         | Typical charge voltage step                                             |                                                                                                                                                          |       | 16                             |       | mV            |
| $V_{BAT(REG)}$               | Charge voltage resolution accuracy                                      | $V_{BAT} = 4.208\text{ V}$ (REG06[7:2] = 010111) or $V_{BAT} = 4.352\text{ V}$ (REG06[7:2] = 100000)<br>$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$ | -0.5% |                                | 0.5%  |               |
| $I_{(CHG\_REG\_RANGE)}$      | Typical fast charge current regulation range                            |                                                                                                                                                          | 0     |                                | 4032  | mA            |
| $I_{(CHG\_REG\_STEP)}$       | Typical fast charge current regulation step                             |                                                                                                                                                          |       | 64                             |       | mA            |
| $I_{(CHG\_REG\_ACC)}$        | Fast charge current regulation accuracy                                 | $V_{BAT} = 3.1\text{ V}$ or $3.8\text{ V}$ , $I_{CHG} = 256\text{ mA}$<br>$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$                               | -20%  |                                | 20%   |               |
|                              |                                                                         | $V_{BAT} = 3.1\text{ V}$ or $3.8\text{ V}$ , $I_{CHG} = 1792\text{ mA}$<br>$T_J = -40^{\circ}\text{C} - 85^{\circ}\text{C}$                              | -5%   |                                | 5%    |               |
| $V_{BAT(LOWV)}$              | Battery LOWV falling threshold                                          | Fast charge to precharge, BATLOWV (REG06[1]) = 1                                                                                                         | 2.6   | 2.8                            | 2.9   | V             |
|                              | Battery LOWV rising threshold                                           | Precharge to fast charge, BATLOWV (REG06[1]) = 1<br>(Typical 200-mV hysteresis)                                                                          | 2.8   | 3.0                            | 3.15  | V             |
|                              | Battery LOWV falling threshold                                          | Fast charge to precharge, BATLOWV (REG06[1]) = 0                                                                                                         | 2.5   | 2.6                            | 2.7   | V             |
|                              | Battery LOWV rising threshold                                           | Precharge to fast charge, BATLOWV (REG06[1]) = 0<br>(Typical 200-mV hysteresis)                                                                          | 2.7   | 2.8                            | 2.9   | V             |
| $I_{(PRECHG\_RANGE)}$        | Precharge current range                                                 |                                                                                                                                                          | 64    |                                | 1024  | mA            |
| $I_{(PRECHG\_STEP)}$         | Typical precharge current step                                          |                                                                                                                                                          |       | 64                             |       | mA            |
| $I_{(PRECHG\_ACC)}$          | Precharge current accuracy                                              | $V_{BAT} = 2.6\text{ V}$ , $I_{PRECHG} = 256\text{ mA}$                                                                                                  | -20%  |                                | 20%   |               |
| $I_{(TERM\_RANGE)}$          | Termination current range                                               |                                                                                                                                                          | 64    |                                | 1024  | mA            |
| $I_{(TERM\_STEP)}$           | Typical termination current step                                        |                                                                                                                                                          |       | 64                             |       | mA            |
| $I_{(TERM\_ACC)}$            | Termination current accuracy                                            | $I_{TERM} = 256\text{ mA}$ , $I_{CHG} \leq 1344\text{ mA}$<br>$T_J = -20^{\circ}\text{C} - 85^{\circ}\text{C}$                                           | -20%  |                                | 20%   |               |
|                              |                                                                         | $I_{TERM} = 256\text{ mA}$ , $I_{CHG} > 1344\text{ mA}$<br>$T_J = -20^{\circ}\text{C} - 85^{\circ}\text{C}$                                              | -20%  |                                | 20%   |               |
| $V_{(SHORT)}$                | Battery short voltage                                                   | VBAT falling                                                                                                                                             |       | 2.0                            |       | V             |
| $V_{(SHORT\_HYST)}$          | Battery short voltage hysteresis                                        | VBAT rising                                                                                                                                              |       | 200                            |       | mV            |
| $I_{(SHORT)}$                | Battery short current                                                   | VBAT < 2.2 V                                                                                                                                             |       | 110                            |       | mA            |

## Electrical Characteristics (continued)

$V_{VBUS\_UVLOZ} < V_{VBUS} < V_{ACOV}$  and  $V_{VBUS} > V_{BAT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                          |                                                                                          | TEST CONDITIONS                                                                                          | MIN   | TYP  | MAX   | UNIT  |
|------------------------------------|------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|-------|------|-------|-------|
| V <sub>(RECHG)</sub>               | Recharge threshold below V <sub>BATREG</sub>                                             | V <sub>BAT</sub> falling, VRECHG (REG06[0] = 0) = 0                                                      |       | 100  |       | mV    |
|                                    |                                                                                          | V <sub>BAT</sub> falling, VRECHG (REG06[0] = 0) = 1                                                      |       | 200  |       | mV    |
| I <sub>BAT(LOAD)</sub>             | Battery discharge load current                                                           | V <sub>BAT</sub> = 4.2 V                                                                                 | 15    |      |       | mA    |
| I <sub>SYS(LOAD)</sub>             | System discharge load current                                                            | V <sub>SYS</sub> = 4.2 V                                                                                 | 30    |      |       | mA    |
| R <sub>ON(BATFET)</sub>            | SYS-BAT MOSFET (BATFET) on-resistance                                                    | T <sub>J</sub> = 25°C                                                                                    |       | 5    | 7     | mΩ    |
|                                    |                                                                                          | T <sub>J</sub> = -40°C - 125°C                                                                           |       | 5    | 10    | mΩ    |
| R <sub>BATSEN</sub>                | BATSEN input resistance                                                                  |                                                                                                          |       | 800  |       | kΩ    |
| INPUT VOLTAGE / CURRENT REGULATION |                                                                                          |                                                                                                          |       |      |       |       |
| V <sub>IN(DPM_RANGE)</sub>         | Typical input voltage regulation range                                                   |                                                                                                          | 3.9   |      | 15.3  | V     |
| V <sub>IN(DPM_STEP)</sub>          | Typical input voltage regulation step                                                    |                                                                                                          |       | 100  |       | mV    |
| V <sub>IN(DPM_ACC)</sub>           | Input voltage regulation accuracy                                                        | VINDPM = 4.4 V, 7.8 V, 10.8 V                                                                            | -3%   |      | 3%    |       |
| I <sub>IN(DPM_RANGE)</sub>         | Typical input current regulation range                                                   |                                                                                                          | 100   |      | 3250  | mA    |
| I <sub>IN(DPM_STEP)</sub>          | Typical input current regulation step                                                    |                                                                                                          |       | 50   |       | mA    |
| I <sub>IN(DPM100_ACC)</sub>        | Input current 100mA regulation accuracy<br>V <sub>BAT</sub> = 5V, current pulled from SW | IINLIM (REG00[5:0]) = 100 mA                                                                             | 85    | 90   | 100   | mA    |
| I <sub>IN(DPM_ACC)</sub>           | Input current regulation accuracy<br>V <sub>BAT</sub> = 5V, current pulled from SW       | USB150, IINLIM (REG00[5:0]) = 150 mA                                                                     | 125   | 135  | 150   | mA    |
|                                    |                                                                                          | USB500, IINLIM (REG00[5:0]) = 500 mA                                                                     | 440   | 470  | 500   | mA    |
|                                    |                                                                                          | USB900, IINLIM (REG00[5:0]) = 900 mA                                                                     | 750   | 825  | 900   | mA    |
|                                    |                                                                                          | Adapter 1.5 A, IINLIM (REG00[5:0]) = 1500 mA                                                             | 1300  | 1400 | 1500  | mA    |
| I <sub>IN(START)</sub>             | Input current regulation during system start up                                          | V <sub>SYS</sub> = 2.2 V, IINLIM (REG00[5:0]) ≥ 200 mA                                                   |       |      | 200   | mA    |
| K <sub>ILIM</sub>                  |                                                                                          | I <sub>INMAX</sub> = K <sub>ILIM</sub> /R <sub>ILIM</sub> , Input Current regulation by ILIM pin = 1.5 A | 290   | 320  | 350   | A x Ω |
| VOK (bq25898)/DSEL (bq25898D)      |                                                                                          |                                                                                                          |       |      |       |       |
| V <sub>VOK_OH</sub>                | Voltage                                                                                  | VBUS > 6 V I(VOK) = 20 mA and I(REGN) = 30 mA                                                            | 4.75  |      | 5.25  | V     |
|                                    |                                                                                          | VBUS = 5 V I(VOK) = 5 mA and I(REGN) = 30 mA                                                             | 4.35  |      | 4.8   | V     |
| V <sub>VOK_OL</sub>                | Voltage                                                                                  | Battery only VBAT = 3.8 V, I(VOK) = -10 mA                                                               |       |      | 0.4   | V     |
| V <sub>DSEL_OH</sub>               | Voltage                                                                                  | I(DSEL) = 20 mA and I(REGN) = 30 mA, VBUS = 5 V                                                          | 1.3   |      |       | V     |
| V <sub>DSEL_OL</sub>               | Voltage                                                                                  | I(DSEL) = -10 mA and I(REGN) = 30 mA, VBUS = 5 V                                                         |       |      | 0.4   | V     |
| D+/D- DETECTION (bq25898D)         |                                                                                          |                                                                                                          |       |      |       |       |
| I <sub>(10UA_ISRC)</sub>           | D+ connection check current source                                                       |                                                                                                          | 7     | 10   | 14    | μA    |
| I <sub>(100UA_ISINK)</sub>         | D+/D- current sink (100 μA)                                                              |                                                                                                          | 50    | 100  | 150   | μA    |
| I <sub>(DPDM_LKG)</sub>            | D+/D- Leakage current                                                                    | D-, switch open                                                                                          | -1    |      | 1     | μA    |
|                                    |                                                                                          | D+, switch open                                                                                          | -1    |      | 1     | μA    |
| I <sub>(1P6MA_ISINK)</sub>         | D+/D- current sink (1.6 mA)                                                              |                                                                                                          | 1.35  | 1.60 | 1.75  | mA    |
| R <sub>(D_-DWN)</sub>              | D- pulldown for connection check                                                         |                                                                                                          | 14.25 |      | 24.8  | kΩ    |
| V <sub>FLOAT_VDPSRC</sub>          | D+/D- Voltage source (HiZ)                                                               | REG01[7:5] = 000 (default) or REG01[4:2] = 000 (default)                                                 |       | HiZ  |       | V     |
| V <sub>0P0_VDSRC</sub>             | D+/D- Voltage source (0 V)                                                               | REG01[7:5] = 001 or REG01[4:2] = 001                                                                     | 0     |      | 0.15  | V     |
| V <sub>0P6_VDSRC</sub>             | D+/D- Voltage source (0.6 V)                                                             | REG01[7:5] = 010 or REG01[4:2] = 010                                                                     | 0.5   | 0.6  | 0.7   | V     |
| V <sub>1P2_DPVSRC</sub>            | D+/D- Voltage source (1.2 V)                                                             | REG01[7:5] = 011 or REG01[4:2] = 011                                                                     | 1.075 | 1.2  | 1.325 | V     |
| V <sub>2P0_DPVSRC</sub>            | D+/D- Voltage source (2.0 V)                                                             | REG01[7:5] = 100 or REG01[4:2] = 100                                                                     | 1.875 | 2    | 2.125 | V     |
| V <sub>2P7_DPVSRC</sub>            | D+/D- Voltage source (2.7 V)                                                             | REG01[7:5] = 101 or REG01[4:2] = 101                                                                     | 2.575 | 2.7  | 2.825 | V     |
| V <sub>3P3_DPVSRC</sub>            | D+/D- Voltage source (3.3 V)                                                             | REG01[7:5] = 110 or REG01[4:2] = 110 or REG01[4:2] = 111                                                 | 3.15  | 3.3  | 3.45  | V     |
| R <sub>DPDM_SHORT</sub>            | D+/D- Short REG01[7:5] = 111                                                             |                                                                                                          |       |      | 200   | Ω     |
| V <sub>(0P4_VTH)</sub>             | D+/D- low comparator threshold                                                           |                                                                                                          | 250   |      | 400   | mV    |
| V <sub>(0P8_VTH)</sub>             | D+ low comparator threshold                                                              |                                                                                                          |       |      | 0.8   | V     |
| V <sub>(2P7_VTH)</sub>             | D+/D- comparator threshold for non-standard adapter detection (Divider 1, 3,or 4)        |                                                                                                          | 2.55  |      | 2.85  | V     |
| V <sub>(2P0_VTH)</sub>             | D+/D- comparator threshold for non-standard adapter detection (Divider 1, 3)             |                                                                                                          | 1.85  |      | 2.15  | V     |
| V <sub>(1P2_VTH)</sub>             | D+/D- comparator threshold for non-standard adapter detection (Divider 2)                |                                                                                                          | 1.05  |      | 1.35  | V     |

## Electrical Characteristics (continued)

$V_{VBUS\_UVLOZ} < V_{VBUS} < V_{ACOV}$  and  $V_{VBUS} > V_{BAT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                                          |                                                                                                                             | TEST CONDITIONS                                                                     | MIN            | TYP     | MAX     | UNIT               |
|----------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|----------------|---------|---------|--------------------|
| <b>BAT OVER-VOLTAGE/CURRENT PROTECTION</b>         |                                                                                                                             |                                                                                     |                |         |         |                    |
| $V_{BAT(OVP)}$                                     | Battery over-voltage threshold                                                                                              | $V_{BAT}$ rising, as percentage of $V_{BAT(REG)}$                                   |                | 104%    |         |                    |
| $V_{BAT(OVP\_HYST)}$                               | Battery over-voltage hysteresis                                                                                             | $V_{BAT}$ falling, as percentage of $V_{BAT(REG)}$                                  |                | 2%      |         |                    |
| $I_{BAT(FET\_OCP)}$                                | System over-current threshold                                                                                               |                                                                                     | 9              |         |         | A                  |
| <b>THERMAL REGULATION AND THERMAL SHUTDOWN</b>     |                                                                                                                             |                                                                                     |                |         |         |                    |
| $T_{REG}$                                          | Junction temperature regulation accuracy                                                                                    | REG08[1:0] = 11                                                                     |                | 120     |         | $^{\circ}\text{C}$ |
| $T_{SHUT}$                                         | Thermal shutdown rising temperature                                                                                         | Temperature rising                                                                  |                | 160     |         | $^{\circ}\text{C}$ |
| $T_{SHUT(HYS)}$                                    | Thermal shutdown hysteresis                                                                                                 | Temperature falling                                                                 |                | 30      |         | $^{\circ}\text{C}$ |
| <b>JEITA THERMISTOR COMPARATOR (BUCK MODE)</b>     |                                                                                                                             |                                                                                     |                |         |         |                    |
| $V_{(T1)}$                                         | T1 ( $0^{\circ}\text{C}$ ) threshold, charge suspended T1 below this temperature.                                           | As percentage to $V_{(REGN)}$                                                       | 72.75%         | 73.25%  | 73.75%  |                    |
| $V_{(T1\_HYS)}$                                    | Charge back to ICHG/2 (REG04[6:0]) and VREG (REG06[7:2]) above this temperature.                                            | As Percentage to $V_{(REGN)}$                                                       |                | 1.4%    |         |                    |
| $V_{(T2)}$                                         | T2 ( $10^{\circ}\text{C}$ ) threshold, charge back to ICHG/2 (REG04[6:0]) and VREG (REG06[7:2]) below this temperature.     | As Percentage to $V_{(REGN)}$                                                       | 67.75%         | 68.25%  | 68.75%  |                    |
| $V_{(T2\_HYS)}$                                    | Charge back to ICHG (REG04[6:0]) and VREG (REG06[7:2]) above this temperature.                                              | As Percentage to $V_{(REGN)}$                                                       |                | 1.4%    |         |                    |
| $V_{(T3)}$                                         | T3 ( $45^{\circ}\text{C}$ ) threshold, charge back to ICHG (REG04[6:0]) and VREG-200mV (REG06[7:2]) above this temperature. | As percentage to $V_{(REGN)}$                                                       | 44.25v         | 44.75%  | 45.25%  |                    |
| $V_{(T3\_HYS)}$                                    | Charge back to ICHG (REG04[6:0]) and VREG (REG06[7:2]) below this temperature.                                              | As Percentage to $V_{(REGN)}$                                                       |                | 1%      |         |                    |
| $V_{(T5)}$                                         | T5 ( $60^{\circ}\text{C}$ ) threshold, charge suspended above this temperature.                                             | As Percentage to $V_{(REGN)}$                                                       | 33.875%        | 34.375% | 34.875% |                    |
| $V_{(T5\_HYS)}$                                    | Charge back to ICHG (REG04[6:0]) and VREG-200mV (REG06[7:2]) below this temperature.                                        | As Percentage to $V_{(REGN)}$                                                       |                | 1.25%   |         |                    |
| <b>COLD/HOT THERMISTOR COMPARATOR (BOOST MODE)</b> |                                                                                                                             |                                                                                     |                |         |         |                    |
| $V_{(BCOLD1)}$                                     | Cold temperature threshold 1, TS pin voltage rising threshold                                                               | As percentage to $V_{REGN}$ REG01[5] = 1 (Approx. $-20^{\circ}\text{C}$ w/ 103AT)   | 79.5%          | 80%     | 80.5%   |                    |
| $V_{(BCOLD1\_HYS)}$                                | Cold temperature threshold 1, TS pin voltage falling threshold                                                              | As percentage to $V_{REGN}$ REG01[5] = 1                                            |                | 1%      |         |                    |
| $V_{(BHOT2)}$                                      | Hot temperature threshold 2, TS pin voltage falling threshold                                                               | As percentage to $V_{REGN}$ REG01[7:6] = 10 (Approx. $65^{\circ}\text{C}$ w/ 103AT) | 30.75%         | 31.25%  | 31.75%  |                    |
| $V_{(BHOT2\_HYS)}$                                 | Hot temperature threshold 2, TS pin voltage rising threshold                                                                | As percentage to $V_{REGN}$ REG01[7:6] = 10                                         |                | 3%      |         |                    |
| <b>PWM</b>                                         |                                                                                                                             |                                                                                     |                |         |         |                    |
| $F_{SW}$                                           | PWM switching frequency, and digital clock                                                                                  | Oscillator frequency                                                                | 1.32           |         | 1.68    | MHz                |
| $D_{MAX}$                                          | Maximum PWM duty cycle                                                                                                      |                                                                                     |                | 97%     |         |                    |
| <b>BOOST MODE OPERATION</b>                        |                                                                                                                             |                                                                                     |                |         |         |                    |
| $V_{(OTG\_REG\_RANGE)}$                            | Typical boost mode regulation voltage range                                                                                 |                                                                                     | 4.55           |         | 5.55    | V                  |
| $V_{(OTG\_REG\_STEP)}$                             | Typical boost Mode Regulation voltage step                                                                                  |                                                                                     |                | 64      |         | mV                 |
| $V_{(OTG\_REG\_ACC)}$                              | Boost mode regulation voltage accuracy                                                                                      | $I_{(VBUS)} = 0\text{ A}$ , BOOSTV = 4.998 V (REG0A[7:4] = 0111)                    | -3%            |         | 3%      |                    |
| $V_{(OTG\_BAT)}$                                   | Battery voltage exiting boost mode                                                                                          | BAT falling, REG03[0] = 0                                                           | 2.7            |         | 2.9     | V                  |
|                                                    |                                                                                                                             | BAT falling, REG03[0] = 1                                                           | 2.4            |         | 2.6     | V                  |
| $I_{(OTG)}$                                        | Typical boost mode output current range                                                                                     |                                                                                     | 0.5            |         | 2.45    | A                  |
| $I_{(OTG\_OCP\_ACC)}$                              | Boost mode RBFET over-current protection accuracy                                                                           | BOOST_LIM = 1.5 A (REG0A[2:0] = 100)                                                | 1.5            |         | 2.0     | A                  |
| $V_{(OTG\_OVP)}$                                   | Boost mode over-voltage threshold                                                                                           | Rising threshold                                                                    | 5.8            | 6       |         | V                  |
| <b>REGN LDO</b>                                    |                                                                                                                             |                                                                                     |                |         |         |                    |
| $V_{(REGN)}$                                       | REGN LDO output voltage                                                                                                     | $V_{(VBUS)} = 9\text{ V}$ , $I_{(REGN)} = 40\text{ mA}$                             | 5.6            | 6       | 6.4     | V                  |
|                                                    |                                                                                                                             | $V_{(VBUS)} = 5\text{ V}$ , $I_{(REGN)} = 20\text{ mA}$                             | 4.7            | 4.8     |         | V                  |
| $I_{(REGN)}$                                       | REGN LDO current limit                                                                                                      | $V_{(VBUS)} = 9\text{ V}$ , $V_{(REGN)} = 3.8\text{ V}$                             | 50             |         |         | mA                 |
| <b>ANALOG-TO-DIGITAL CONVERTER (ADC)</b>           |                                                                                                                             |                                                                                     |                |         |         |                    |
| RES                                                | Resolution                                                                                                                  | Rising threshold                                                                    |                | 7       |         | bits               |
| $V_{BAT(RANGE)}$                                   | Typical battery voltage range                                                                                               | $V_{(VBUS)} > V_{BAT} + V_{(SLEEP)}$ or OTG mode is enabled                         | 2.304          |         | 4.848   | V                  |
|                                                    |                                                                                                                             | $V_{(VBUS)} < V_{BAT} + V_{(SLEEP)}$ and OTG mode is disabled                       | $V_{SYS\_MIN}$ |         | 4.848   | V                  |
| $V_{(BAT\_RES)}$                                   | Typical battery voltage resolution                                                                                          |                                                                                     |                | 20      |         | mV                 |

## Electrical Characteristics (continued)

$V_{VBUS\_UVLOZ} < V_{VBUS} < V_{ACOV}$  and  $V_{VBUS} > V_{BAT} + V_{SLEEP}$ ,  $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$  and  $T_J = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                                                | TEST CONDITIONS                                                     | MIN            | TYP   | MAX   | UNIT          |
|----------------------------------------------------------|---------------------------------------------------------------------|----------------|-------|-------|---------------|
| $V_{(SYS\_RANGE)}$ Typical system voltage range          | $V_{(VBUS)} > V_{BAT} + V_{(SLEEP)}$ or OTG mode is enabled         | 2.304          |       | 4.848 | V             |
|                                                          | $V_{(VBUS)} < V_{BAT} + V_{(SLEEP)}$ and OTG mode is disabled       | $V_{SYS\_MIN}$ |       | 4.848 | V             |
| $V_{(SYS\_RES)}$ Typical system voltage resolution       |                                                                     |                | 20    |       | mV            |
| $V_{(VBUS\_RANGE)}$ Typical $V_{VBUS}$ voltage range     | $V_{(VBUS)} > V_{BAT} + V_{(SLEEP)}$ or OTG mode is enabled         | 2.6            |       | 15.3  | V             |
| $V_{(VBUS\_RES)}$ Typical $V_{VBUS}$ voltage resolution  |                                                                     |                | 100   |       | mV            |
| $I_{BAT(RANGE)}$ Typical battery charge current range    | $V_{(VBUS)} > V_{BAT} + V_{(SLEEP)}$ and $V_{BAT} > V_{BAT(SHORT)}$ | 0              |       | 4.032 | A             |
| $I_{BAT(RES)}$ Typical battery charge current resolution |                                                                     |                | 50    |       | mA            |
| $V_{(TS\_RANGE)}$ Typical TS voltage range               |                                                                     | 21%            |       | 80%   |               |
| $V_{(TS\_RES)}$ Typical TS voltage resolution            |                                                                     |                | 0.47% |       |               |
| <b>LOGIC I/O PIN (OTG, CE, PSEL, QON)</b>                |                                                                     |                |       |       |               |
| $V_{IH}$ Input high threshold level                      |                                                                     | 1.3            |       |       | V             |
| $V_{IL}$ Input low threshold level                       |                                                                     |                |       | 0.4   | V             |
| $I_{IN(BIAS)}$ High level leakage current                | Pull-up rail 1.8 V                                                  |                |       | 1     | $\mu\text{A}$ |
| $V_{(QON)}$ Internal /QON pull-up                        | Battery only mode                                                   |                | BAT   |       | V             |
|                                                          | $V_{(VBUS)} = 9\text{ V}$                                           |                | 5.8   |       | V             |
|                                                          | $V_{(VBUS)} = 5\text{ V}$                                           |                | 4.3   |       | V             |
| $R_{(QON)}$ Internal /QON pull-up resistance             |                                                                     |                | 200   |       | k $\Omega$    |
| <b>LOGIC I/O PIN (INT, STAT, PG)</b>                     |                                                                     |                |       |       |               |
| $V_{OL}$ Output low threshold level                      | Sink Current = 5 mA, Sink current                                   |                |       | 0.4   | V             |
| $I_{OUT\_BIAS}$ High level leakage current               | Pull-up rail 1.8 V                                                  |                |       | 1     | $\mu\text{A}$ |
| <b>I2C INTERFACE (SCL, SDA)</b>                          |                                                                     |                |       |       |               |
| $V_{IH}$ Input high threshold level, SCL and SDA         | Pull-up rail 1.8 V                                                  | 1.3            |       |       | V             |
| $V_{IL}$ Input low threshold level                       | Pull-up rail 1.8 V                                                  |                |       | 0.4   | V             |
| $V_{OL}$ Output low threshold level                      | Sink Current = 5 mA, Sink current                                   |                |       | 0.4   | V             |
| $I_{BIAS}$ High level leakage current                    | Pull-up rail 1.8 V                                                  |                |       | 1     | $\mu\text{A}$ |

## 8.6 Timing Requirements

|                                                                                      |                                                  | MIN  | NOM | MAX  | UNIT          |
|--------------------------------------------------------------------------------------|--------------------------------------------------|------|-----|------|---------------|
| <b>VBUS/BAT POWER UP</b>                                                             |                                                  |      |     |      |               |
| $t_{BADSRC}$ Bad adapter detection duration                                          |                                                  |      | 30  |      | msec          |
| <b>BAT OVER-VOLTAGE PROTECTION</b>                                                   |                                                  |      |     |      |               |
| $t_{BATOVP}$ Battery over-voltage deglitch time to disable charge                    |                                                  |      | 1   |      | $\mu\text{s}$ |
| <b>BATTERY CHARGER</b>                                                               |                                                  |      |     |      |               |
| $t_{RECHG}$ Recharge deglitch time                                                   |                                                  |      | 20  |      | msec          |
| <b>Current Pulse Control</b>                                                         |                                                  |      |     |      |               |
| $t_{PUMPX\_STOP}$ Current pulse control stop pulse                                   |                                                  | 430  |     | 570  | msec          |
| $t_{PUMPX\_ON1}$ Current pulse control long on pulse                                 |                                                  | 240  |     | 360  | msec          |
| $t_{PUMPX\_ON2}$ Current pulse control short on pulse                                |                                                  | 70   |     | 130  | msec          |
| $t_{PUMPX\_OFF}$ Current pulse control off pulse                                     |                                                  | 70   |     | 130  | msec          |
| $t_{PUMPX\_DLY}$ Current pulse control stop start delay                              |                                                  | 80   |     | 225  | msec          |
| <b>BATTERY MONITOR</b>                                                               |                                                  |      |     |      |               |
| $t_{CONV}$ Conversion time                                                           | CONV_RATE(REG02[6]) = 0                          |      | 8   | 1000 | msec          |
| <b>QON and SHIPMODE TIMING</b>                                                       |                                                  |      |     |      |               |
| $t_{SHIPMODE}$ $\overline{\text{QON}}$ low time to turn on BATFET and exit ship mode | $T_J = -10^{\circ}\text{C} - 60^{\circ}\text{C}$ | 0.8  |     | 1.3  | sec           |
| $t_{QON\_RST}$ $\overline{\text{QON}}$ low time to enable full system reset          | $T_J = -10^{\circ}\text{C} - 60^{\circ}\text{C}$ | 15.5 |     | 23   | sec           |
| $t_{BATFET\_RST}$ BATFET off time during full system reset                           | $T_J = -10^{\circ}\text{C} - 60^{\circ}\text{C}$ | 250  |     | 400  | msec          |

**Timing Requirements (continued)**

|                                         |                         |                                                   | MIN  | NOM  | MAX  | UNIT |
|-----------------------------------------|-------------------------|---------------------------------------------------|------|------|------|------|
| $t_{SM\_DLY}$                           | Enter ship mode delay   | $T_J = -10^{\circ}\text{C} - 60^{\circ}\text{C}$  | 10   |      | 15   | sec  |
| <b>I2C INTERFACE</b>                    |                         |                                                   |      |      |      |      |
| $f_{SCL}$                               | SCL clock frequency     |                                                   |      |      | 400  | KHz  |
| <b>DIGITAL CLOCK and WATCHDOG TIMER</b> |                         |                                                   |      |      |      |      |
| $f_{LPDIG}$                             | Digital low power clock | REGN LDO disabled                                 | 18   | 30   | 45   | KHz  |
| $f_{DIG}$                               | Digital clock           | REGN LDO enabled                                  | 1320 | 1500 | 1680 | KHz  |
| $t_{WDT}$                               | Watchdog reset time     | WATCHDOG<br>(REG07[5:4])=11, REGN LDO<br>disabled | 100  | 160  |      | sec  |
|                                         |                         | WATCHDOG<br>(REG07[5:4])=11, REGN LDO<br>enabled  | 136  | 160  |      | sec  |

## 8.7 Typical Characteristics

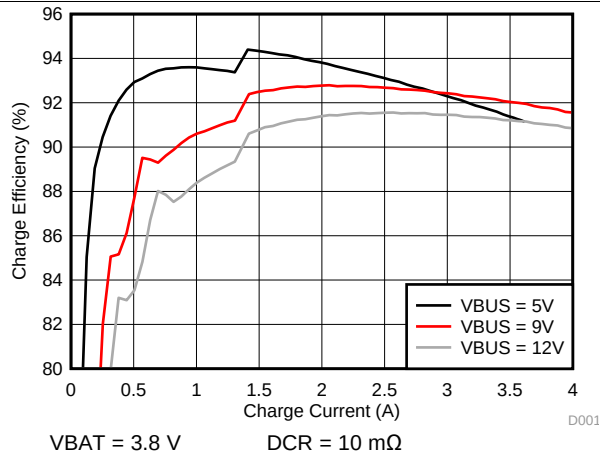


图 1. Charge Efficiency vs Charge Current

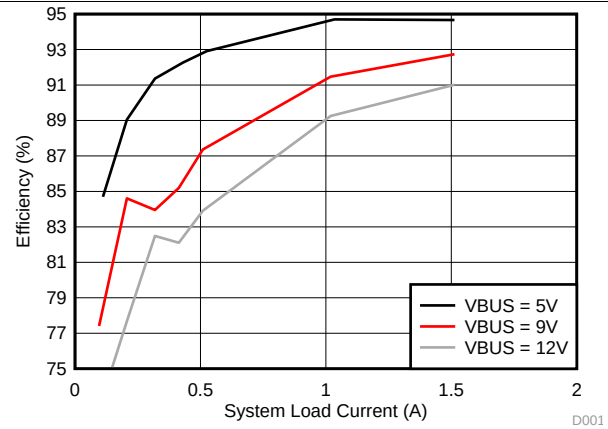


图 2. System Light Load Efficiency vs System Light Load Current

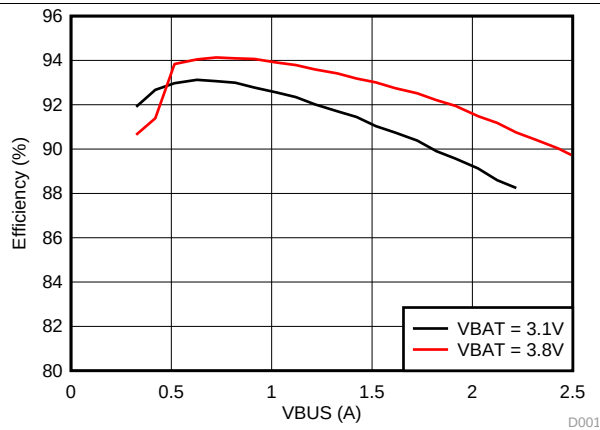


图 3. Boost Mode Efficiency vs VBUS Load Current

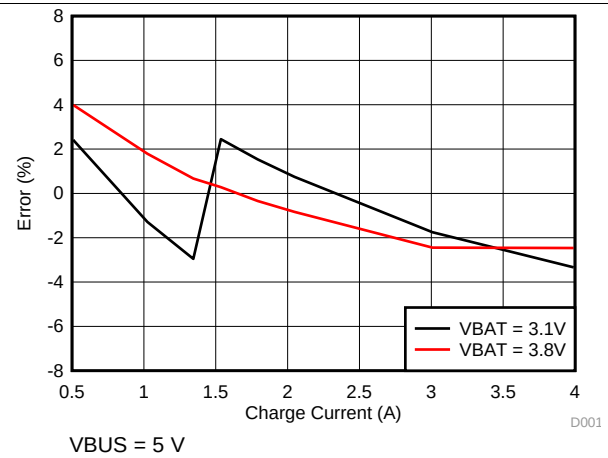


图 4. Charge Current Accuracy vs Charge Current I²C Setting

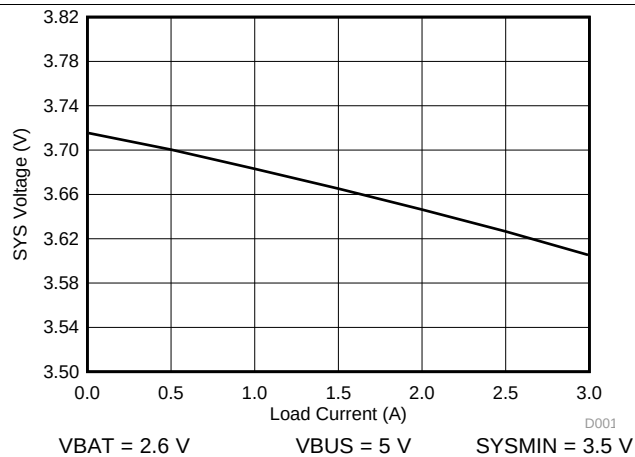


图 5. SYS Voltage Regulation vs System Load Current

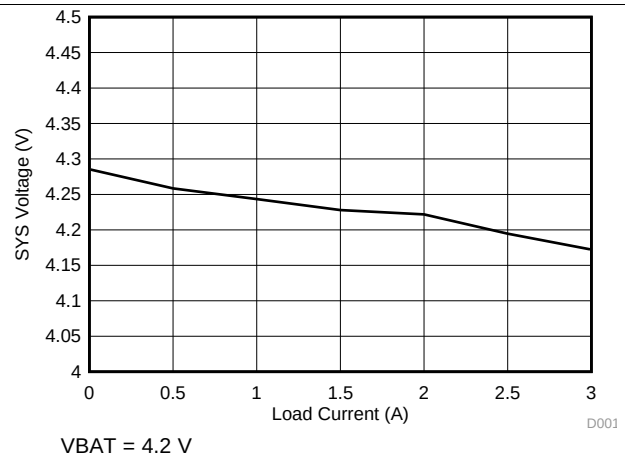


图 6. SYS Voltage Regulation vs System Load Current

## Typical Characteristics (接下页)

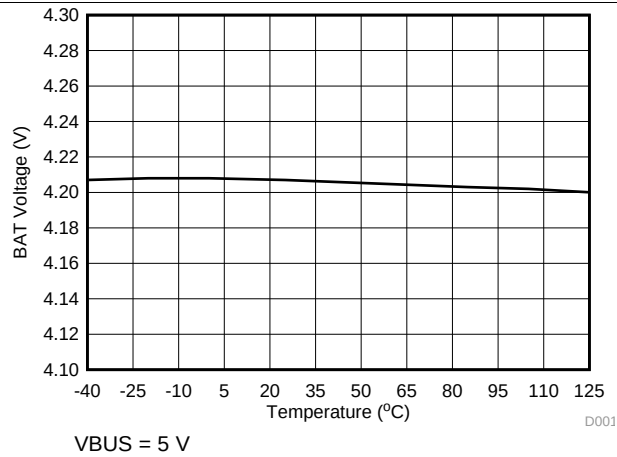


图 7. BAT Voltage vs Temperature

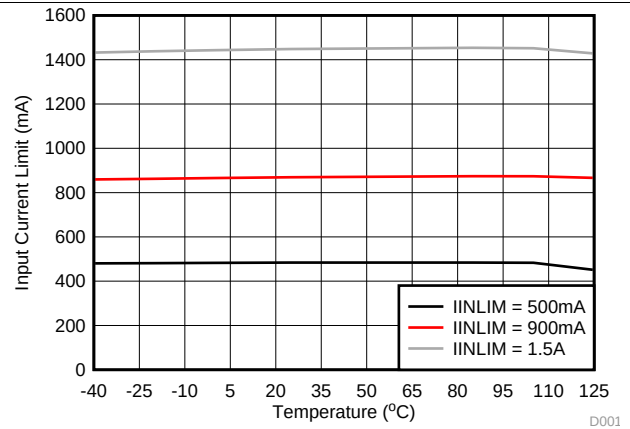


图 8. Input Current Limit vs Temperature

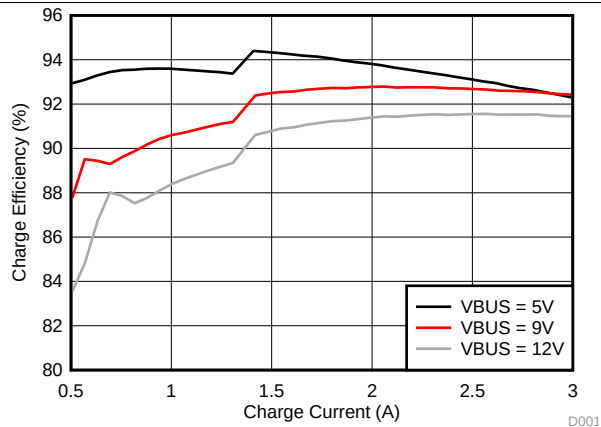


图 9. Charge Efficiency

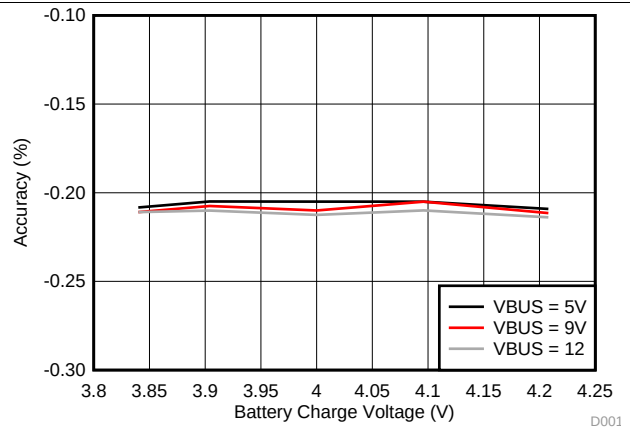


图 10. Charge Voltage Accuracy



The device is a highly integrated 4-A switch-mode battery charger for single cell Li-Ion and Li-polymer battery. It is highly integrated with the input reverse-blocking FET (RBFET, Q1), high-side switching FET (HSFET, Q2), low-side switching FET (LSFET, Q3), and battery FET (BATFET, Q4). The device also integrates the bootstrap diode for the high-side gate drive.

The diagram illustrates the internal architecture of the bq25898 battery charger IC. It shows the flow of signals and power from the input source (VBUS) through various control blocks to the output (BAT). Key components include:

- Input Source Detection:** Detects the input source (USB, battery, etc.) and provides signals like  $D+$ ,  $D-$ ,  $PSEL$ ,  $OTG$ ,  $INT$ ,  $STAT$ , and  $/PG$ .
- USB Adapter:** Manages USB communication, including  $SCL$ ,  $SDA$ ,  $/CE$ , and  $BATSEN$  signals.
- ADC Control:** Controls the ADC for monitoring various voltages and currents.
- Charge Control State Machine:** Manages the charging process, including  $RECHRG$ ,  $TERMINATION$ ,  $BATLOWV$ ,  $BATSHORT$ , and  $SUSPEND$  states.
- Regulation and Control:** Includes blocks for  $REGN$  LDO,  $CONVERTER CONTROL$ ,  $Q1$  Gate Control,  $Q2$  Gate Control,  $Q3$  Gate Control, and  $Q4$  Gate Control.
- Transistors:**  $RBFET (Q1)$ ,  $HSFET (Q2)$ ,  $LSFET (Q3)$ , and  $BATFET (Q4)$  are used for power regulation and switching.
- Monitoring:** Includes a  $Battery Sensing Thermistor$  and various current and voltage monitors like  $I_{CHG}$ ,  $I_{BAT}$ ,  $V_{BAT}$ , and  $V_{REG}$ .

## 9.2 Feature Description

### 9.2.1 Device Power-On-Reset (POR)

The internal bias circuits are powered from the higher voltage of VBUS and BAT. When VBUS rises above  $V_{VBUS\_UVLOZ}$  or BAT rises above  $V_{BAT\_UVLOZ}$ , the sleep comparator, battery depletion comparator and BATFET driver are active. I<sup>2</sup>C interface is ready for communication and all the registers are reset to default value. The host can access all the registers after POR.

### 9.2.2 Device Power Up from Battery without Input Source

If only battery is present and the voltage is above depletion threshold ( $V_{BAT\_DPLZ}$ ), the BATFET turns on and connects battery to system. The REGN LDO stays off to minimize the quiescent current. The low  $R_{DS(ON)}$  of BATFET and the low quiescent current on BAT minimize the conduction loss and maximize the battery run time. The device always monitors the discharge current through BATFET (see [Supplement Mode](#)). When the system is overloaded or shorted ( $I_{BAT} > I_{BATFET\_OCP}$ ), the device turns off BATFET immediately and sets BATFET\_DIS bit to indicate BATFET is disabled until the input source plugs in again or one of the methods describe in [BATFET Enable \(Exit Shipping Mode\)](#) is applied to re-enable BATFET.

### 9.2.3 Device Power Up from Input Source

When an input source is plugged in, the device checks the input source voltage to turn on REGN LDO and all the bias circuits. It detects and sets the input current limit before the buck converter is started when AUTO\_DPDM\_EN bit is set. The power up sequence from input source is as listed:

1. Power Up REGN LDO
2. Poor Source Qualification
3. [Input Source Type Detection](#) based on D+/D- (bq25898D) or PSEL (bq25898) to set default Input Current Limit (IINLIM) register and input source type
4. Input Voltage Limit Threshold Setting (VINDPM threshold)
5. Converter Power-up

#### 9.2.3.1 Power Up REGN Regulation (LDO)

The REGN LDO supplies internal bias circuits as well as the HSFET and LSFET gate drive. The LDO also provides bias rail to TS external resistors. The pull-up rail of STAT and PG can be connected to REGN as well. The REGN is enabled when all the below conditions are valid.

1. VBUS above  $V_{VBUS\_UVLOZ}$
2. VBUS above  $V_{BAT} + V_{SLEEPZ}$  in buck mode or VBUS below  $V_{BAT} + V_{SLEEP}$  in boost mode
3. After 220 ms delay is completed

If one of the above conditions is not valid, the device is in high impedance mode (HIZ) with REGN LDO off. The device draws less than  $I_{VBUS\_HIZ}$  from VBUS during HIZ state. The battery powers up the system when the device is in HIZ.

#### 9.2.3.2 Poor Source Qualification

After REGN LDO powers up, the device checks the current capability of the input source. The input source has to meet the following requirements in order to start the buck converter.

1. VBUS voltage below  $V_{ACOV}$
2. VBUS voltage above  $V_{VBUSMIN}$  when pulling  $I_{BADSRC}$  (typical 30mA)

Once the input source passes all the conditions above, the status register bit VBUS\_GD is set high and the INT pin is pulsed to signal to the host. If the device fails the poor source detection, it repeats poor source qualification every 2 seconds.

#### 9.2.3.3 Input Source Type Detection

After the VBUS\_GD bit is set and REGN LDO is powered, the charger device runs [Input Source Type Detection](#) when AUTO\_DPDM\_EN bit is set.

## Feature Description (接下页)

The bq25898D follows the USB Battery Charging Specification 1.2 (BC1.2) and to detect input source (SDP/CDP/DCP) and non-standard adapter through USB D+/D- lines. In addition, when USB DCP is detected, it initiates adjustable high voltage adapter handshake on D+/D-. The device supports MaxCharge™ handshake when MAXC\_EN or HVDCP\_EN is set. The bq25898 sets input current limit through PSEL and OTG pins.

After input source type detection, an INT pulse is asserted to the host. In addition, the following registers and pin are changed:

1. Input Current Limit (IINLIM) register is changed to set current limit
2. PG\_STAT bit is set
3.  $\overline{\text{PG}}$  pin goes low (bq25898)

The host can over-write IINLIM register to change the input current limit if needed. The charger input current is always limited by the lower of IINLIM register or ILIM pin at all-time regardless of Input Current Optimizer (ICO) is enable or disabled.

When AUTO\_DPDM\_EN is disabled, the [Input Source Type Detection](#) is bypassed. The Input Current Limit (IINLIM) register, VBUS\_STAT, and SPD\_STAT bits are unchanged from previous values.

### 9.2.3.3.1 D+/D- Detection Sets Input Current Limit (bq25898D)

The bq25898D contains a D+/D- based input source detection to set the input current limit automatically. The D+/D- detection includes standard USB BC1.2, non-standard adapter, and adjustable high voltage adapter detections. When input source is plugged-in, the device starts standard USB BC1.2 detections. The USB BC1.2 is capable to identify Standard Downstream Port (SDP), Charging Downstream Port (CDP), and Dedicated Charging Port (DCP). When the Data Contact Detection (DCD) timer of 500ms is expired, the non-standard adapter detection is applied to set the input current limit.

When DCP is detected, the device initiates adjustable high voltage adapter handshake including MaxCharge™, etc. The handshake connects combinations of voltage source(s) and/or current sink on D+/D- to signal input source to raise output voltage from 5 V to 9 V / 12 V. The adjustable high voltage adapter handshake can be disabled by clearing MAXC\_EN and/or HVDCP\_EN bits .

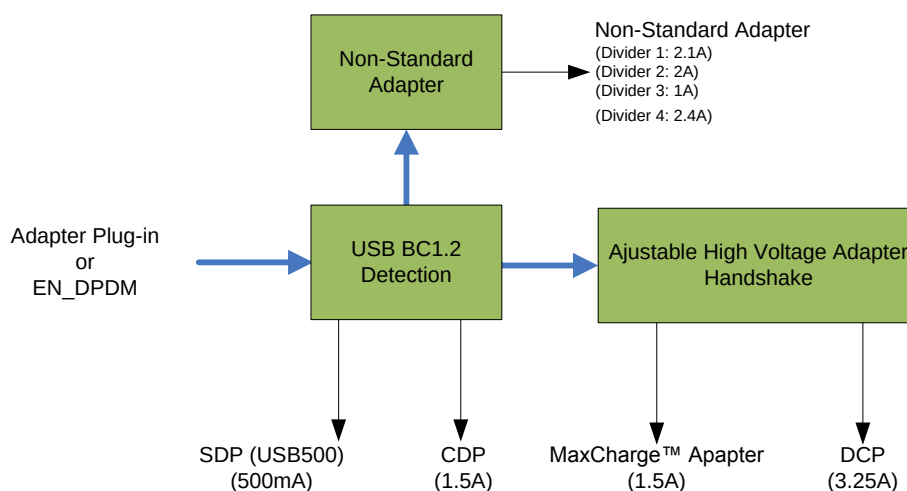


图 11. USB D+/D- Detection

**表 1. Non-Standard Adapter Detection**

| NON-STANDARD ADAPTER | D+ THRESHOLD                   | D- THRESHOLD                   | INPUT CURRENT LIMIT |
|----------------------|--------------------------------|--------------------------------|---------------------|
| Divider 1            | $V_{D+}$ within $V_{2P7\_VTH}$ | $V_{D-}$ within $V_{2P0\_VTH}$ | 2.1A                |
| Divider 2            | $V_{D+}$ within $V_{1P2\_VTH}$ | $V_{D-}$ within $V_{1P2\_VTH}$ | 2A                  |
| Divider 3            | $V_{D+}$ within $V_{2P0\_VTH}$ | $V_{D-}$ within $V_{2P7\_VTH}$ | 1A                  |
| Divider 4            | $V_{D+}$ within $V_{2P7\_VTH}$ | $V_{D-}$ within $V_{2P7\_VTH}$ | 2.4A                |

**表 2. Adjustable High Voltage Adapter D+/D- Output Configurations**

| ADJUSTABLE HIGH VOLTAGE HANDSHAKE | D+                 | D-                 | OUTPUT |
|-----------------------------------|--------------------|--------------------|--------|
| MaxCharge (12V)                   | $I_{1P6MA\_ISINK}$ | $V_{3p45\_VSR}$    | 12 V   |
| MaxCharge (9V)                    | $V_{3p45\_VSR}$    | $I_{1P6MA\_ISINK}$ | 9 V    |

After the [Input Source Type Detection](#) is done, an INT pulse is asserted to the host. In addition, the following registers including Input Current Limit register (IINLIM), VBUS\_STAT, and SDP\_STAT are updated as below:

**表 3. bq25898D Result**

| D+/D- DETECTION  | INPUT CURRENT LIMIT (IINLIM) | SDP_STAT | VBUS_STAT |
|------------------|------------------------------|----------|-----------|
| USB SDP (USB500) | 500 mA                       | 1        | 001       |
| USB CDP          | 1.5 A                        | 1        | 010       |
| USB DCP          | 3.25 A                       | 1        | 011       |
| Divider 3        | 1 A                          | 1        | 110       |
| Divider 1        | 2.1 A                        | 1        | 110       |
| Divider 4        | 2.4 A                        | 1        | 110       |
| Divider 2        | 2 A                          | 1        | 110       |
| MaxCharge        | 1.5 A                        | 1        | 100       |
| Unknown Adapter  | 500 mA                       | 1        | 101       |

#### 9.2.3.3.2 PSEL Pin Sets Input Current Limit (bq25898)

The bq25898 has PSEL interface for input current limit setting to interface with USB PHY. It directly takes the USB PHY device output to decide whether the input is USB host or charging port. To implement USB100 in the system, the host can enter HiZ mode by setting EN\_HIZ bit after 2 min charging with 500 mA input current limit.

**表 4. bq25898 Result**

| INPUT DETECTION  | BAT VOLTAGE | PSEL PIN | INPUT CURRENT LIMIT (IINLIM) | SDP_STAT | VBUS_STAT |
|------------------|-------------|----------|------------------------------|----------|-----------|
| USB SDP (USB500) | X           | High     | 500 mA                       | 1        | 001       |
| Adapter          | X           | Low      | 3.25 A                       | 1        | 010       |

#### 9.2.3.3.3 Force Input Current Limit Detection

In host mode, the host can force the device to run by setting FORCE\_DPDM bit. After the detection is completed, FORCE\_DPDM bit returns to 0 by itself and Input Result is updated.

#### 9.2.3.4 Input Voltage Limit Threshold Setting (VINDPM Threshold)

The device supports wide range of input voltage limit (3.9 V – 14 V) for high voltage charging and provides two methods to set Input Voltage Limit (VINDPM) threshold to facilitate autonomous detection.

##### 1. Absolute VINDPM (FORCE\_VINDPM=1)

By setting FORCE\_VINDPM bit to 1, the VINDPM threshold setting algorithm is disabled. Register VINDPM is writable and allows host to set the absolute threshold of VINDPM function.

##### 2. Relative VINDPM based on VINDPM\_OS registers (FORCE\_VINDPM=0) (Default)

When FORCE\_VINDPM bit is 0 (default), the VINDPM threshold setting algorithm is enabled. The VINDPM register is read only and the charger controls the register by using VINDPM Threshold setting algorithm. The algorithm allows a wide range of adapter ( $V_{VBUS\_OP}$ ) to be used with flexible VINDPM threshold.

After Input Voltage Limit Threshold is set, an INT pulse is generated to signal to the host.

### 9.2.3.5 Converter Power-Up

After the input current limit is set, the converter is enabled and the HSFET and LSFET start switching. If battery charging is disabled, BATFET turns off. Otherwise, BATFET stays on to charge the battery.

The device provides soft-start when system rail is ramped up. When the system rail is below 2.2 V, the input current limit is forced to the lower of 200 mA or IINLIM register setting. After the system rises above 2.2 V, the device limits input current to the lower value of ILIM pin and IILIM register (ICO\_EN = 0) or IDPM\_LIM register (ICO\_EN = 1).

As a battery charger, the device deploys a highly efficient 1.5 MHz step-down switching regulator. The fixed frequency oscillator keeps tight control of the switching frequency under all conditions of input voltage, battery voltage, charge current and temperature, simplifying output filter design.

A type III compensation network allows using ceramic capacitors at the output of the converter. An internal saw-tooth ramp is compared to the internal error control signal to vary the duty cycle of the converter. The ramp height is proportional to the PMID voltage to cancel out any loop gain variation due to a change in input voltage.

In order to improve light-load efficiency, the device switches to PFM control at light load when battery is below minimum system voltage setting or charging is disabled. During the PFM operation, the switching duty cycle is set by the ratio of SYS and VBUS.

### 9.2.4 Input Current Optimizer (ICO)

The device provides innovative Input Current Optimizer (ICO) to identify maximum power point without overload the input source. The algorithm automatically identify maximum input current limit of power source without entering VINDPM to avoid input source overload.

This feature is enabled by default (ICO\_EN=1) and can be disabled by setting ICO\_EN bit to 0. After DCP or MaxCharge type input source is detected based on the procedures previously described ([Input Source Type Detection](#)). The algorithm runs automatically when ICO\_EN bit is set. The algorithm can also be forced to execute by setting FORCE\_ICO bit regardless of input source type detected.

The actual input current limit used by the [Dynamic Power Management](#) is reported in IDPM\_LIM register while Input Current Optimizer is enabled (ICO\_EN = 1) or set by IINLIM register when the algorithm is disabled (ICO\_EN = 0). In addition, the current limit is clamped by ILIM pin unless EN\_ILIM bit is 0 to disable ILIM pin function.

### 9.2.5 Boost Mode Operation from Battery

The device supports boost converter operation to deliver power from the battery to other portable devices through USB port. The boost mode output current rating meets the USB On-The-Go 500 mA (BOOST\_LIM bits = 000) output requirement. The maximum output current is up to 2.4 A. The boost operation can be enabled if the conditions are valid:

1. BAT above  $BAT_{LOWV}$
2. VBUS less than  $BAT + V_{SLEEP}$  (in sleep mode)
3. Boost mode operation is enabled (OTG pin HIGH and OTG\_CONFIG bit =1)
4. Voltage at TS (thermistor) pin is within range configured by Boost Mode Temperature Monitor as configured by BHOT and BCOLD bits
5. After 30 ms delay from boost mode enable

In boost mode, the device employs a 500 KHz or 1.5 MHz (selectable using BOOST\_FREQ bit) step-up switching regulator based on system requirements. To avoid frequency change during boost mode operations, write to boost frequency configuration bit (BOOST\_FREQ) is ignored when OTG\_CONFIG is set.

During boost mode, the status register VBUS\_STAT bits is set to 111, the VBUS output is 5V by default (selectable via BOOSTV register bits) and the output current can reach up to 2.4 A, selected via I<sup>2</sup>C (BOOST\_LIM bits). The boost output is maintained when BAT is above  $V_{OTG\_BAT}$  threshold.

## 9.2.6 Power Path Management

The device accommodates a wide range of input sources from USB, wall adapter, to car battery. The device provides automatic power path selection to supply the system (SYS) from input source (VBUS), battery (BAT), or both.

### 9.2.6.1 Narrow VDC Architecture

The device deploys Narrow VDC architecture (NVDC) with BATFET separating system from battery. The minimum system voltage is set by SYS\_MIN bits. Even with a fully depleted battery, the system is regulated above the minimum system voltage (default 3.5 V).

When the battery is below minimum system voltage setting, the BATFET operates in linear mode (LDO mode), and the system is regulated above the minimum system voltage setting. As the battery voltage rises above the minimum system voltage, BATFET is fully on and the voltage difference between the system and battery is the  $V_{DS}$  of BATFET. The status register VSYS\_STAT bit goes high when the system is in minimum system voltage regulation.

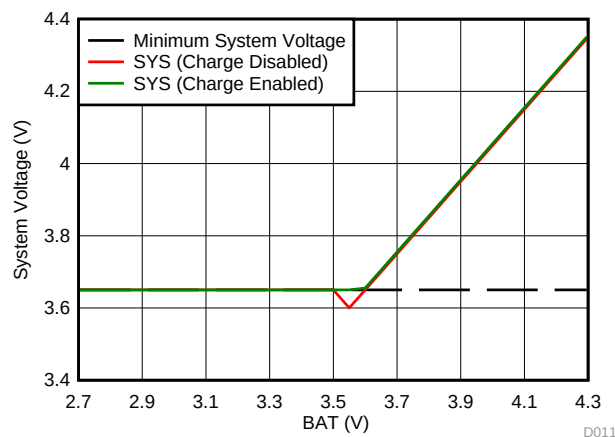


图 12. V(SYS) vs V(BAT)

### 9.2.6.2 Dynamic Power Management

To meet maximum current limit in USB spec and avoid over loading the adapter, the device features Dynamic Power Management (DPM), which continuously monitors the input current and input voltage. When input source is over-loaded, either the current exceeds the input current limit (IINLIM or IDPM\_LIM) or the voltage falls below the input voltage limit (VINDPM). The device then reduces the charge current until the input current falls below the input current limit and the input voltage rises above the input voltage limit.

When the charge current is reduced to zero, but the input source is still overloaded, the system voltage starts to drop. Once the system voltage falls below the battery voltage, the device automatically enters the [Supplement Mode](#) where the BATFET turns on and battery starts discharging so that the system is supported from both the input source and battery.

During DPM mode, the status register bits VDPM\_STAT (VINDPM) and/or IDPM\_STAT (IINDPM) is/are set high. [图 13](#) shows the DPM response with 9V/1.2A adapter, 3.2-V battery, 2.8-A charge current and 3.4-V minimum system voltage setting.

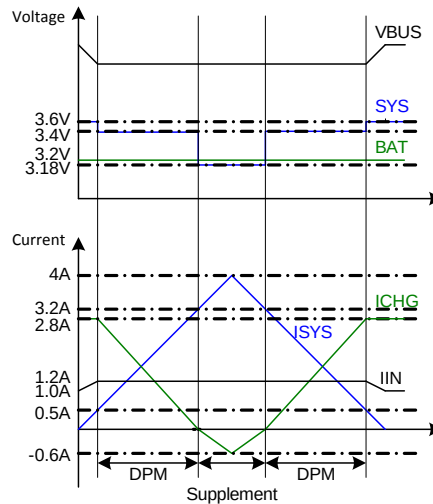


图 13. DPM Response

### 9.2.6.3 Supplement Mode

When the system voltage falls below the battery voltage, the BATFET turns on and the BATFET gate is regulated the gate drive of BATFET so that the minimum BATFET VDS stays at 30 mV when the current is low. This prevents oscillation from entering and exiting the [Supplement Mode](#). As the discharge current increases, the BATFET gate is regulated with a higher voltage to reduce  $R_{DS(ON)}$  until the BATFET is in full conduction. At this point onwards, the BATFET VDS linearly increases with discharge current. 图 14 shows the V-I curve of the BATFET gate regulation operation. BATFET turns off to exit [Supplement Mode](#) when the battery is below battery depletion threshold.

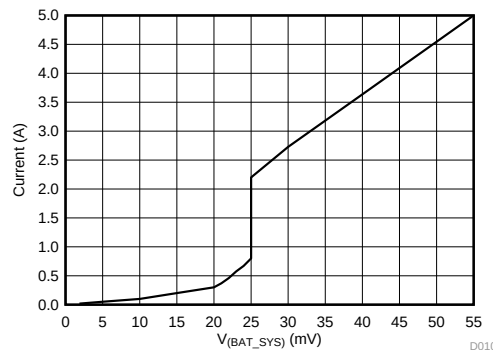


图 14. BATFET V-I Curve

## 9.2.7 Battery Charging Management

The device charges 1-cell Li-Ion battery with up to 4-A charge current for high capacity battery. The 5-mΩ BATFET improves charging efficiency and minimize the voltage drop during discharging.

### 9.2.7.1 Autonomous Charging Cycle

With battery charging enabled (CHG\_CONFIG bit = 1 and  $\overline{CE}$  pin is low), the device autonomously completes a charging cycle without host involvement. The device default charging parameters are listed in 表 5. The host can always control the charging operations and optimize the charging parameters by writing to the corresponding registers through I<sup>2</sup>C.



**表 5. Charging Parameter Default Setting**

| DEFAULT MODE        | bq25898D | bq25898 |
|---------------------|----------|---------|
| Charging Voltage    | 4.208 V  | 4.208 V |
| Charging Current    | 2.048 A  | 2.048 A |
| Pre-charge Current  | 128 mA   | 128 mA  |
| Termination Current | 256 mA   | 256 mA  |
| Temperature Profile | JEITA    | JEITA   |
| Safety Timer        | 12 hour  | 12 hour |

A new charge cycle starts when the following conditions are valid:

- Converter starts
- Battery charging is enabled by setting CHG\_CONFIG bit, /CE pin is low and ICHG register is not 0 mA
- No thermistor fault on TS pin
- No safety timer fault
- BATFET is not forced to turn off (BATFET\_DIS bit = 0)

The charger device automatically terminates the charging cycle when the charging current is below termination threshold, charge voltage is above recharge threshold, and device not in DPM mode or thermal regulation. When a full battery voltage is discharged below recharge threshold (threshold selectable via VRECHG bit), the device automatically starts a new charging cycle. After the charge is done, either toggle CE pin or CHG\_CONFIG bit can initiate a new charging cycle.

The STAT output indicates the charging status of charging (LOW), charging complete or charge disable (HIGH) or charging fault (Blinking). The STAT output can be disabled by setting STAT\_DIS bit. In addition, the status register (CHRG\_STAT) indicates the different charging phases: 00-charging disable, 01-precharge, 10-fast charge (constant current) and constant voltage mode, 11-charging done. Once a charging cycle is completed, an INT is asserted to notify the host.

### 9.2.7.2 Battery Charging Profile

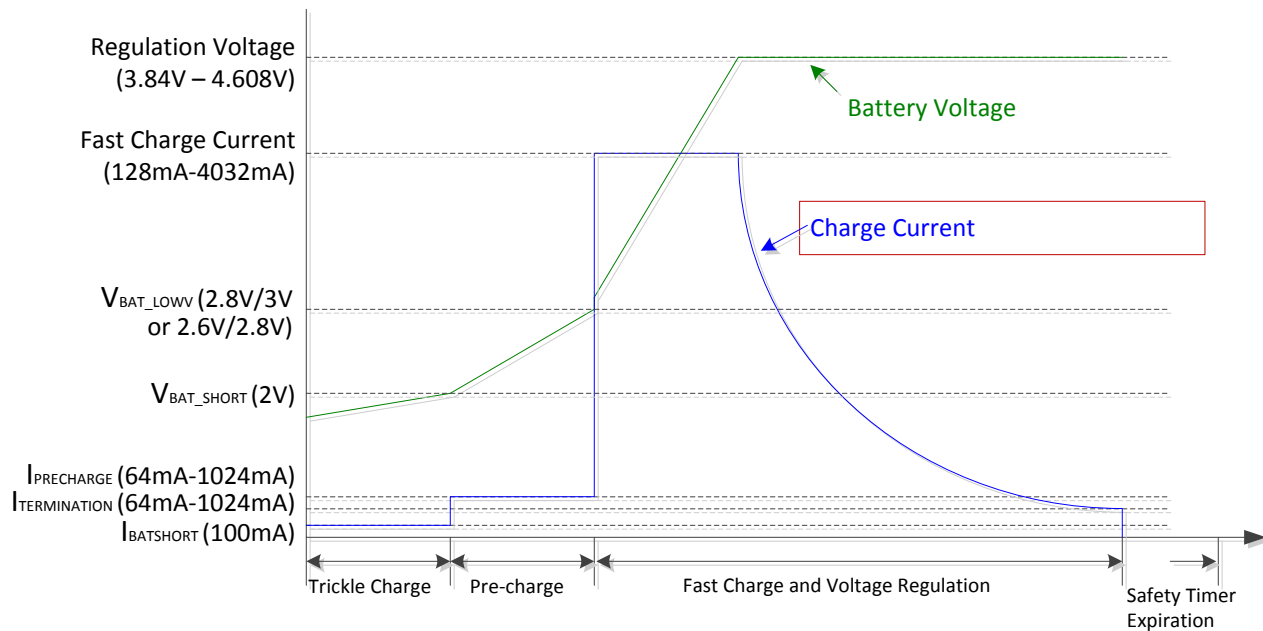
The device charges the battery in three phases: preconditioning, constant current and constant voltage. At the beginning of a charging cycle, the device checks the battery voltage and regulates current / voltage.

**表 6. Charging Current Setting**

| VBAT      | CHARGING CURRENT      | REG DEFAULT SETTING       | CHRG_STAT |
|-----------|-----------------------|---------------------------|-----------|
| < 2 V     | I <sub>BATSHORT</sub> | –                         | 01        |
| 2 V – 3 V | I <sub>PRECHG</sub>   | 0 mA (precharge disabled) | 01        |
| > 3 V     | I <sub>CHG</sub>      | 2048 mA                   | 10        |



If the charger device is in DPM regulation or thermal regulation during charging, the charging current can be less than the programmed value. In this case, termination is temporarily disabled and the charging safety timer is counted at half the clock rate.



**图 15. Battery Charging Profile**

### 9.2.7.3 Charging Termination

The device terminates a charge cycle when the battery voltage is above recharge threshold, and the current is below termination current. After the charging cycle is completed, the BATFET turns off. The converter keeps running to power the system, and BATFET can turn on again to engage [Supplement Mode](#).

When termination occurs, the status register CHRG\_STAT is set to 11, and an INT pulse is asserted to the host. Termination is temporarily disabled when the charger device is in input current, voltage or thermal regulation. Termination can be disabled by writing 0 to EN\_TERM bit prior to charge termination.

### 9.2.7.4 Resistance Compensation (IRCOMP)

For high current charging system, resistance between charger output and battery cell terminal such as board routing, connector, MOSFETs and sense resistor can force the charging process to move from constant current to constant voltage too early and increase charge time. To speed up the charging cycle, the device provides resistance compensation (IRCOMP) feature which can extend the constant current charge time to delivery maximum power to battery.

The device allows the host to compensate for the resistance by increasing the voltage regulation set point based on actual charge current and the resistance as shown below. For safe operation, the host should set the maximum allowed regulation voltage register ( $V_{CLAMP}$ ) and the minimum resistance compensation (BATCOMP).

$$V_{REG\_ACTUAL} = V_{REG} + \min(I_{CHRG\_ACTUAL} \times BATCOMP, V_{CLAMP}) \quad (1)$$

### 9.2.7.5 Thermistor Qualification

#### 9.2.7.5.1 JEITA Guideline Compliance in Charge Mode

To improve the safety of charging Li-ion batteries, JEITA guideline was released on April 20, 2007. The guideline emphasized the importance of avoiding a high charge current and high charge voltage at certain low and high temperature ranges.

The device continuously monitors battery temperature by measuring the voltage between the TS pins and ground, typically determined by a negative temperature coefficient thermistor (NTC) and an external voltage divider. The device compares this voltage against its internal thresholds to determine if charging is allowed. To initiate a charge cycle, the voltage on TS pin must be within the  $V_{T1}$  to  $V_{T5}$  thresholds. If TS voltage exceeds the T1–T5 range, the controller suspends charging and waits until the battery temperature is within the T1 to T5 range. At cool temperature (T1–T2), JEITA recommends the charge current to be reduced to at least half of the charge current or lower. At warm temperature (T3–T5), JEITA recommends charge voltage below nominal charge voltage.

The device provides flexible voltage/current settings beyond the JEITA requirement. The voltage setting at warm temperature (T3–T5) can be 200 mV below charge voltage (JEITA\_VSET=0). The current setting at cool temperature (T1–T2) can be further reduced to 20% or 50% of fast charge current (JEITA\_ISET bit).

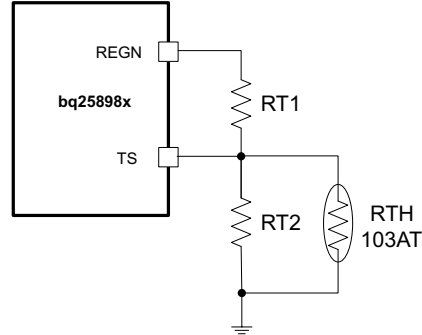


图 16. TS Resistor Network

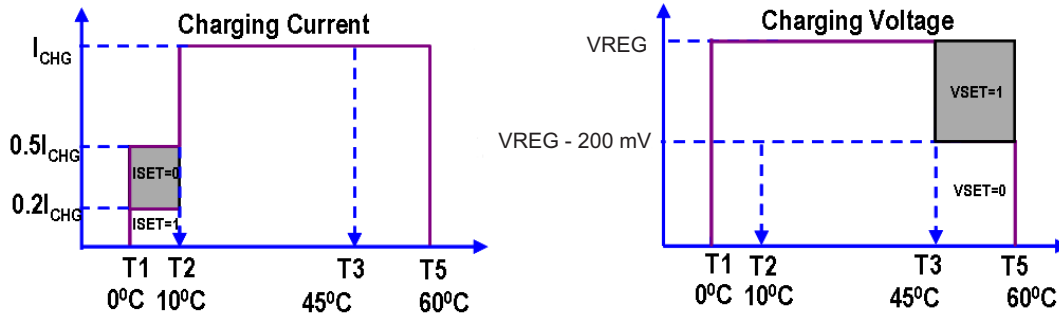


图 17. Charging Values

Assuming a 103AT NTC thermistor on the battery pack as shown in 图 16, the value RT1 and RT2 can be determined by using 公式 2:

$$RT2 = \frac{V_{VREGN} \times RTH_{COLD} \times RTH_{HOT} \times \left( \frac{1}{VT1} - \frac{1}{VT5} \right)}{RTH_{HOT} \times \left( \frac{V_{VREGN}}{VT5} - 1 \right) - RTH_{COLD} \times \left( \frac{V_{VREGN}}{VT1} - 1 \right)}$$

$$RT1 = \frac{\frac{V_{VREGN}}{VT1} - 1}{\frac{1}{RT2} + \frac{1}{RTH_{COLD}}}$$

(2)

Select 0°C to 60°C range for Li-ion or Li-polymer battery,

$RTH_{T1} = 27.28 \text{ k}\Omega$

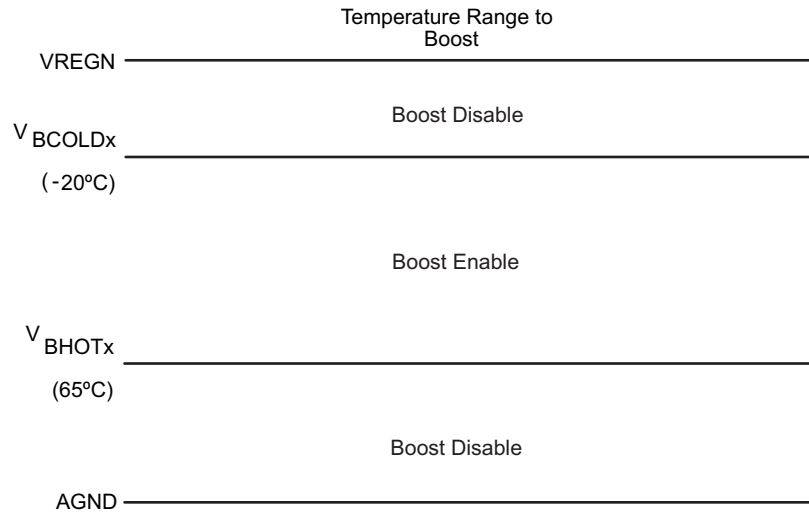
$RTH_{T5} = 3.02 \text{ k}\Omega$

$RT1 = 5.24 \text{ k}\Omega$ 
 $RT2 = 30.31 \text{ k}\Omega$ 

During JEITA cool, the bq25898x terminates when the charge current has reached 20% or 50% of termination current setting, depending on the JT\_IREDUCE bit. During JEITA warm, the bq25898x terminates when the charge current reaches the termination current setting.

### 9.2.7.5.2 Cold/Hot Temperature Window in Boost Mode

For battery protection during boost mode, the device monitors the battery temperature to be within the  $V_{BCOLD1}$  to  $V_{BHOT2}$  thresholds unless boost mode temperature is disabled by setting BHOT bits to 11. When temperature is outside of the temperature thresholds, the boost mode is suspended. Once temperature is within thresholds, the boost mode is recovered.



**图 18. TS Pin Thermistor Sense Thresholds in Boost Mode**

### 9.2.7.6 Charging Safety Timer

The device has built-in safety timer to prevent extended charging cycle due to abnormal battery conditions. The safety timer is 4 hours when the battery is below  $V_{BATLOWV}$  threshold. The user can program fast charge safety timer through I<sup>2</sup>C (CHG\_TIMER bits). When safety timer expires, the fault register CHRG\_FAULT bits are set to 11 and an INT is asserted to the host. The safety timer feature can be disabled via I2C by setting EN\_TIMER bit.

During input voltage, current or thermal regulation, the safety timer counts at half clock rate as the actual charge current is likely to be below the register setting. For example, if the charger is in input current regulation (IDPM\_STAT = 1) throughout the whole charging cycle, and the safety time is set to 5 hours, the safety timer will expire in 10 hours. This half clock rate feature can be disabled by writing 0 to TMR2X\_EN bit.

### 9.2.8 Battery Monitor

The device includes a battery monitor to provide measurements of VBUS voltage, battery voltage, system voltage, thermistor ratio, and charging current, and charging current based on the device's modes of operation. The measurements are reported in Battery Monitor Registers (REG0E-REG12). The battery monitor can be configured as two conversion modes by using CONV\_RATE bit: one-shot conversion (default) and 1 second continuous conversion.

For one-shot conversion (CONV\_RATE = 0), the CONV\_START bit can be set to start the conversion. During the conversion, the CONV\_START is set and it is cleared by the device when conversion is completed. The conversion result is ready after  $t_{CONV}$  (maximum 1 second).

For continuous conversion (CONV\_RATE = 1), the CONV\_RATE bit can be set to initiate the conversion. During active conversion, the CONV\_START is set to indicate conversion is in progress. The battery monitor provides conversion result every 1 second automatically. The battery monitor exits continuous conversion mode when CONV\_RATE is cleared.

When battery monitor is active, the REGN power is enabled and can increase device quiescent current.

**表 7. Battery Monitor Modes of Operation**

| PARAMETER                             | REGISTER | MODES OF OPERATION |            |                     |                   |
|---------------------------------------|----------|--------------------|------------|---------------------|-------------------|
|                                       |          | CHARGE MODE        | BOOST MODE | DISABLE CHARGE MODE | BATTERY ONLY MODE |
| Battery Voltage ( $V_{BAT}$ )         | REG0E    | Yes                | Yes        | Yes                 | Yes               |
| System Voltage ( $V_{SYS}$ )          | REG0F    | Yes                | Yes        | Yes                 | Yes               |
| Temperature (TS) Voltage ( $V_{TS}$ ) | REG10    | Yes                | Yes        | Yes                 | Yes               |
| VBUS Voltage ( $V_{VBUS}$ )           | REG11    | Yes                | Yes        | Yes                 | NA                |
| Charge Current ( $I_{BAT}$ )          | REG12    | Yes                | NA         | NA                  | NA                |

## 9.2.9 Status Outputs ( $\overline{PG}$ , STAT, and INT)

### 9.2.9.1 Power Good Indicator ( $\overline{PG}$ )

In bq25898, the  $\overline{PG}$  goes LOW to indicate a good input source when:

1. VBUS above  $V_{VBUS\_UVLO}$
2. VBUS above battery (not in sleep)
3. VBUS below  $V_{ACOV}$  threshold
4. VBUS above  $V_{VBUSMIN}$  (typical 3.8 V) when  $I_{BADSRC}$  (typical 30 mA) current is applied (not a poor source)
5. Completed [Input Source Type Detection](#)

### 9.2.9.2 Charging Status Indicator (STAT)

The device indicates charging state on the open drain STAT pin. The STAT pin can drive LED as shown in [Figure 49](#). The STAT pin function can be disabled by setting STAT\_DIS bit.

**表 8. STAT Pin State**

| CHARGING STATE                                                                                                                 | STAT INDICATOR   |
|--------------------------------------------------------------------------------------------------------------------------------|------------------|
| Charging in progress (including recharge)                                                                                      | LOW              |
| Charging complete                                                                                                              | HIGH             |
| Sleep mode, charge disable                                                                                                     | HIGH             |
| Charge suspend (Input overvoltage, TS fault, timer fault, input or system overvoltage)<br>Boost Mode suspend (due to TS Fault) | blinking at 1 Hz |

### 9.2.9.3 Interrupt to Host (INT)

In some applications, the host does not always monitor the charger operation. The INT notifies the system on the device operation. The following events will generate 256- $\mu$ s INT pulse.

- USB/adaptor source identified (through PSEL or DPDM detection, with OTG pin)
- Good input source detected
  - VBUS above battery (not in sleep)
  - VBUS below  $V_{ACOV}$  threshold
  - VBUS above  $V_{VBUSMIN}$  (typical 3.8 V) when  $I_{BADSRC}$  (typical 30 mA) current is applied (not a poor source)
- Input removed
- Charge Complete
- Any FAULT event in REG0C

When a fault occurs, the charger device sends out INT and keeps the fault state in REG0C until the host reads the fault register. Before the host reads REG0C and all the faults are cleared, the charger device would not send any INT upon new faults. To read the current fault status, the host has to read REG0C two times consecutively. The 1<sup>st</sup> read reports the pre-existing fault register status and the 2<sup>nd</sup> read reports the current fault register status.

## 9.2.10 BATFET (Q4) Control

### 9.2.10.1 BATFET Disable Mode (Shipping Mode)

To extend battery life and minimize power when system is powered off during system idle, shipping, or storage, the device can turn off BATFET so that the system voltage is zero to minimize the battery leakage current. When the host set BATFET\_DIS bit, the charger can turn off BATFET immediately or delay by  $t_{SM\_DLY}$  as configured by BATFET\_DLY bit.

### 9.2.10.2 BATFET Enable (Exit Shipping Mode)

When the BATFET is disabled (in shipping mode) and indicated by setting BATFET\_DIS, one of the following events can enable BATFET to restore system power:

1. Plug in adapter
2. Clear BATFET\_DIS bit
3. Set REG\_RST bit to reset all registers including BATFET\_DIS bit to default (0)
4. A logic high to low transition on  $\overline{QON}$  pin with  $t_{SHIPMODE}$  deglitch time to enable BATFET to exit shipping mode

### 9.2.10.3 BATFET Full System Reset

The BATFET functions as a load switch between battery and system when input source is not plugged-in. By changing the state of BATFET from off to on, system connects to SYS can be effectively have a power-on-reset. The  $\overline{QON}$  pin supports push-button interface to reset system power without host by change the state of BATFET.

When the  $\overline{QON}$  pin is driven to logic low for  $t_{QON\_RST}$  (typical 15 seconds) while input source is not plugged in and BATFET is enabled (BATFET\_DIS=0), the BATFET is turned off for  $t_{BATFET\_RST}$  and then it is re-enabled to reset system power. This function can be disabled by setting BATFET\_RST\_EN bit to 0.

## 9.2.11 Current Pulse Control Protocol

The device provides the control to generate the VBUS current pulse protocol to communicate with adjustable high voltage adapter in order to signal adapter to increase or decrease output voltage. To enable the interface, the EN\_PUMPX bit must be set. Then the host can select the increase/decrease voltage pulse by setting one of the PUMPX\_UP or PUMPX\_DN bit (but not both) to start the VBUS current pulse sequence. During the current pulse sequence, the PUMPX\_UP and PUMPX\_DN bits are set to indicate pulse sequence is in progress and the device pulses the input current limit between current limit set forth by IINLIM or IDPM\_LIM register and the 100mA current limit ( $I_{INDPM100\_ACC}$ ). When the pulse sequence is completed, the input current limit is returned to value set by IINLIM or IDPM\_LIM register and the PUMPX\_UP or PUMPX\_DN bit is cleared. In addition, the EN\_PUMPX can be cleared during the current pulse sequence to terminate the sequence and force charger to return to input current limit as set forth by the IINLIM or IDPM\_LIM register immediately. When EN\_PUMPX bit is low, write to PUMPX\_UP and PUMPX\_DN bit would be ignored and have no effect on VBUS current limit.

## 9.2.12 Input Current Limit on ILIM

For safe operation, the device has an additional hardware pin on ILIM to limit maximum input current on ILIM pin. The input maximum current is set by a resistor from ILIM pin to ground as:

$$I_{NMAX} = \frac{K_{ILIM}}{R_{ILIM}} \quad (3)$$

The actual input current limit is the lower value between ILIM setting and register setting (IINLIM). For example, if the register setting is 111111 for 3.25 A, and ILIM has a 232-Ω resistor ( $K_{ILIM} = 350$  max.) to ground for 1.5 A, the input current limit is 1.5 A. ILIM pin can be used to set the input current limit rather than the register settings when EN\_ILIM bit is set. The device regulates ILIM pin at 0.8 V. If ILIM voltage exceeds 0.8 V, the device enters input current regulation (Refer to [Dynamic Power Management](#) section).

The ILIM pin can also be used to monitor input current when EN\_ILIM is enabled. The voltage on ILIM pin is proportional to the input current. ILIM pin can be used to monitor the input current following 公式 4:

$$I_N = \frac{K_{ILIM} \times V_{ILIM}}{R_{ILIM} \times 0.8 \text{ V}} \quad (4)$$

For example, if ILIM pin is set with 260-Ω resistor, and the ILIM voltage is 0.4 V, the actual input current 0.557 A - 0.67 A (based on KILM specified). If ILIM pin is open, the input current is limited to zero since ILIM voltage floats above 0.8 V. If ILIM pin is short, the input current limit is set by the register.

The ILIM pin function can be disabled by setting EN\_ILIM bit to 0. When the pin is disabled, both input current limit function and monitoring function are not available.

## 9.2.13 Thermal Regulation and Thermal Shutdown

### 9.2.13.1 Thermal Protection in Buck Mode

The device monitors the internal junction temperature  $T_J$  to avoid overheat the chip and limits the IC surface temperature in buck mode. When the internal junction temperature exceeds the preset thermal regulation limit (TREG bits), the device lowers down the charge current. The wide thermal regulation range from 60°C to 120°C allows the user to optimize the system thermal performance.

During thermal regulation, the actual charging current is usually below the programmed battery charging current. Therefore, termination is disabled, the safety timer runs at half the clock rate, and the status register THERM\_STAT bit goes high.

Additionally, the device has thermal shutdown to turn off the converter and BATFET when IC surface temperature exceeds  $T_{SHUT}$ . The fault register CHRG\_FAULT is set to 10 and an INT is asserted to the host. The BATFET and converter is enabled to recover when IC temperature is below  $T_{SHUT\_HYS}$ .

#### 9.2.13.1.1 Thermal Protection in Boost Mode

The device monitors the internal junction temperature to provide thermal shutdown during boost mode. When IC surface temperature exceeds  $T_{SHUT}$ , the boost mode is disabled (converter is turned off) by setting OTG\_CONFIG bit low and BATFET is turned off. When IC surface temperature is below  $T_{SHUT\_HYS}$ , the BATFET is enabled automatically to allow system to restore and the host can re-enable OTG\_CONFIG bit to recover.

## 9.2.14 Voltage and Current Monitoring in Buck and Boost Mode

### 9.2.14.1 Voltage and Current Monitoring in Buck Mode

The device closely monitors the input and system voltage, as well as HSFET current for safe buck and boost mode operations.

#### 9.2.14.1.1 Input Overvoltage (ACOV)

The input voltage for buck mode operation is  $V_{VBUS\_OP}$ . If VBUS voltage exceeds  $V_{ACOV}$ , the device stops switching immediately. During input over voltage (ACOV), the fault register CHRG\_FAULT bits sets to 01. An INT is asserted to the host.

#### 9.2.14.1.2 System Overvoltage Protection (SYSOVP)

The charger device clamps the system voltage during load transient so that the components connect to system would not be damaged due to high voltage. When SYSOVP is detected, the converter stops immediately to clamp the overshoot.

### 9.2.14.2 Voltage and Current Monitoring in Boost Mode

The device closely monitors the VBUS voltage, as well as RBFET and LSFET current to ensure safe boost mode operation.

#### 9.2.14.2.1 VBUS Overcurrent Protection

The charger device closely monitors the RBFET (Q1), and LSFET (Q3) current to ensure safe boost mode operation. During overcurrent condition when output current exceed ( $I_{OTG\_OCP}$ ) the device operates in hiccup mode for protection. While in hiccup mode cycle, the device turns off RBFET for  $t_{OTG\_OCP\_OFF}$  (30 ms typical) and turns on RBFET for  $t_{OTG\_OCP\_ON}$  (250 μs typical) in an attempt to restart. If the overcurrent condition is removed, the boost converter returns to normal operation. When overcurrent condition continues to exist, the device repeats the hiccup cycle until overcurrent condition is removed. When overcurrent condition is detected the fault register bit BOOST\_FAULT is set high to indicate fault in boost operation. An INT is also asserted to the host.

### 9.2.14.2.2 Boost Mode Overvoltage Protection

When the VBUS voltage rises above regulation target and exceeds  $V_{OTG\_OVP}$ , the device enters overvoltage protection which stops switching, clears OTG\_CONFIG bit and exits boost mode. During the overvoltage duration, the fault register bit (BOOST\_FAULT) is set high to indicate fault in boost operation. An INT is also asserted to the host.

## 9.2.15 Battery Protection

### 9.2.15.1 Battery Overvoltage Protection (BATOVP)

The battery overvoltage limit is clamped at 4% above the battery regulation voltage. When battery over voltage occurs, the charger device immediately disables charge. The fault register BAT\_FAULT bit goes high and an INT is asserted to the host.

### 9.2.15.2 Battery Over-Discharge Protection

When battery is discharged below  $V_{BAT\_DPL}$ , the BATFET is turned off to protect battery from over discharge. To recover from over-discharge, an input source is required at VBUS. When an input source is plugged in, the BATFET turns on. The battery is charged with  $I_{BATSHORT}$  (typically 100 mA) current when the  $V_{BAT} < V_{SHORT}$ , or precharge current as set in IPRECHG register when the battery voltage is between  $V_{SHORT}$  and  $V_{BATLOWV}$ .

### 9.2.15.3 System Overcurrent Protection

When the system is shorted or significantly overloaded ( $I_{BAT} > I_{BATOP}$ ) so that its current exceeds the overcurrent limit, the device latches off BATFET. Section [BATFET Enable \(Exit Shipping Mode\)](#) can reset the latch-off condition and turn on BATFET.

## 9.2.16 Serial Interface

The device uses I<sup>2</sup>C compatible interface for flexible charging parameter programming and instantaneous device status reporting. I<sup>2</sup>C is a bi-directional 2-wire serial interface. Only two open-drain bus lines are required: a serial data line (SDA) and a serial clock line (SCL). Devices can be considered as masters or slaves when performing data transfers. A master is the device which initiates a data transfer on the bus and generates the clock signals to permit that transfer. At that time, any device addressed is considered a slave.

The device operates as a slave device with address 6BH, receiving control inputs from the master device like micro controller or a digital signal processor through REG00-REG14. Register read beyond REG14 (0x14) returns 0xFF. The I<sup>2</sup>C interface supports both standard mode (up to 100 kbits), and fast mode (up to 400 kbits). When the bus is free, both lines are HIGH. The SDA and SCL pins are open drain and must be connected to the positive supply voltage via a current source or pull-up resistor.

### 9.2.16.1 Data Validity

The data on the SDA line must be stable during the HIGH period of the clock. The HIGH or LOW state of the data line can only change when the clock signal on the SCL line is LOW. One clock pulse is generated for each data bit transferred.

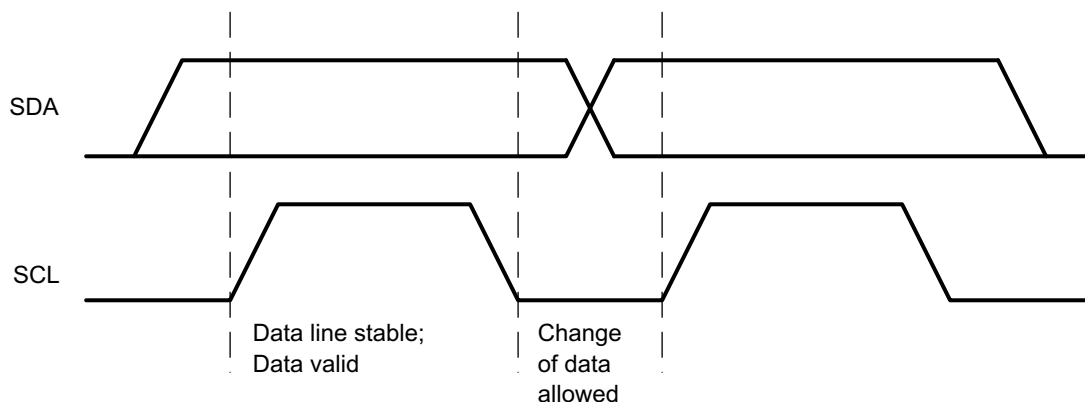


图 19. Bit Transfer on the I<sup>2</sup>C Bus



### 9.2.16.2 START and STOP Conditions

All transactions begin with a START (S) and can be terminated by a STOP (P). A HIGH to LOW transition on the SDA line while SCL is HIGH defines a START condition. A LOW to HIGH transition on the SDA line when the SCL is HIGH defines a STOP condition.

START and STOP conditions are always generated by the master. The bus is considered busy after the START condition, and free after the STOP condition.

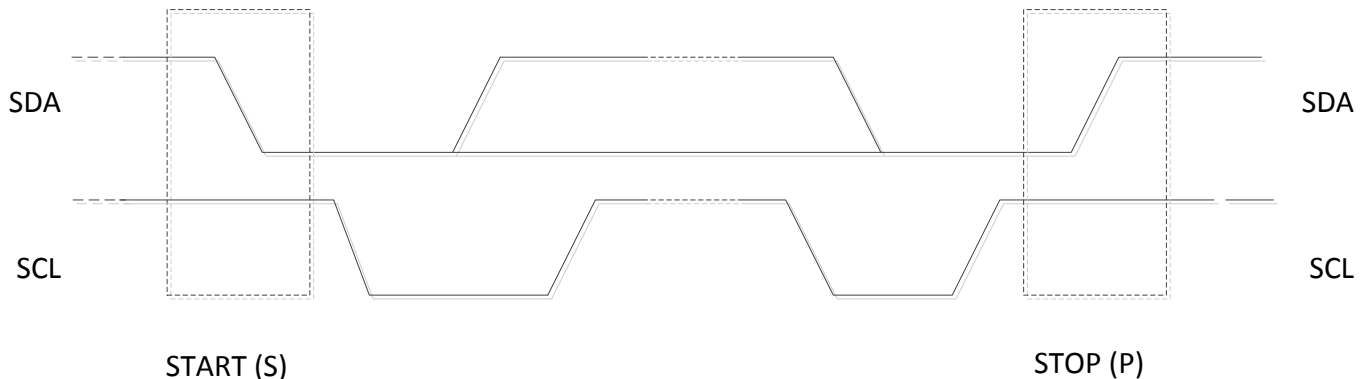


图 20. START and STOP conditions

### 9.2.16.3 Byte Format

Every byte on the SDA line must be 8 bits long. The number of bytes to be transmitted per transfer is unrestricted. Each byte has to be followed by an Acknowledge bit. Data is transferred with the Most Significant Bit (MSB) first. If a slave cannot receive or transmit another complete byte of data until it has performed some other function, it can hold the clock line SCL low to force the master into a wait state (clock stretching). Data transfer then continues when the slave is ready for another byte of data and release the clock line SCL.

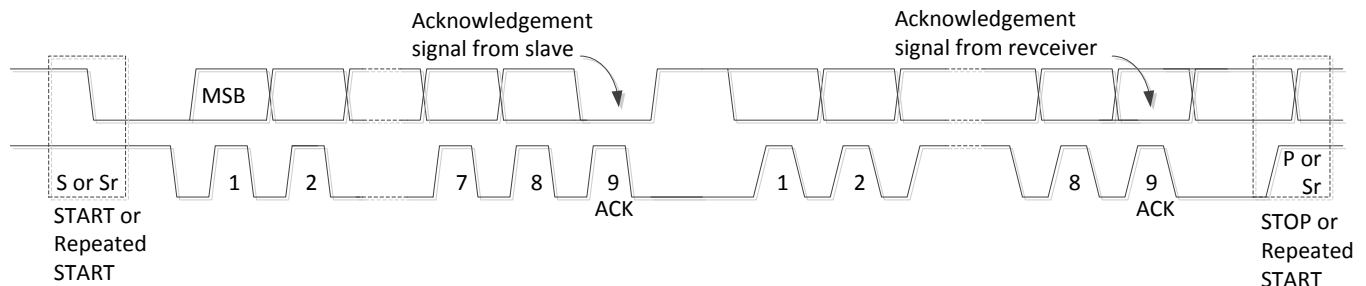


图 21. Data Transfer on the I<sup>2</sup>C Bus

### 9.2.16.4 Acknowledge (ACK) and Not Acknowledge (NACK)

The acknowledge takes place after every byte. The acknowledge bit allows the receiver to signal the transmitter that the byte was successfully received and another byte may be sent. All clock pulses, including the acknowledge 9<sup>th</sup> clock pulse, are generated by the master.

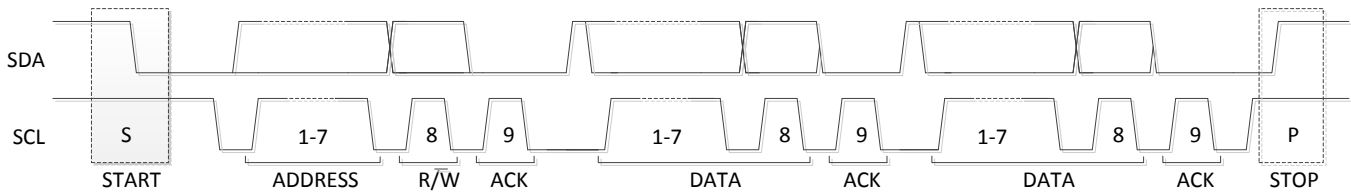
The transmitter releases the SDA line during the acknowledge clock pulse so the receiver can pull the SDA line LOW and it remains stable LOW during the HIGH period of this clock pulse.

When SDA remains HIGH during the 9<sup>th</sup> clock pulse, this is the Not Acknowledge signal. The master can then generate either a STOP to abort the transfer or a repeated START to start a new transfer.

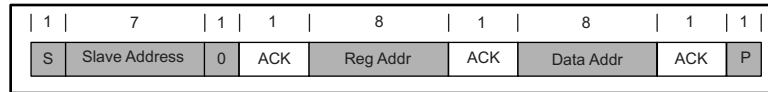
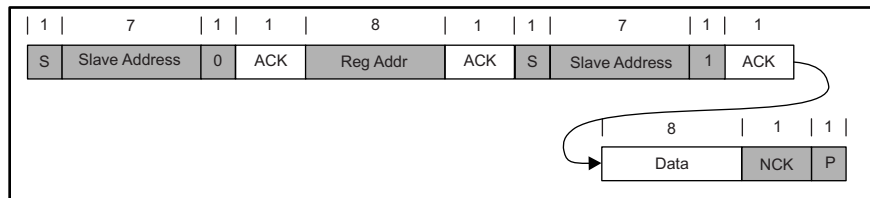
### 9.2.16.5 Slave Address and Data Direction Bit

After the START, a slave address is sent. This address is 7 bits long followed by the eighth bit as a data direction bit (bit R/W). A zero indicates a transmission (WRITE) and a one indicates a request for data (READ).




**图 22. Complete Data Transfer**

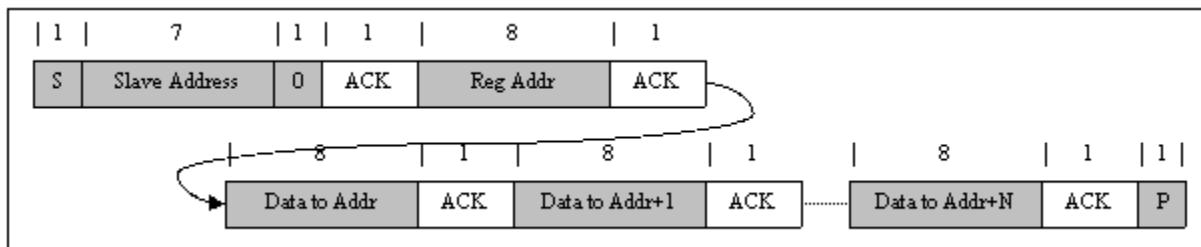
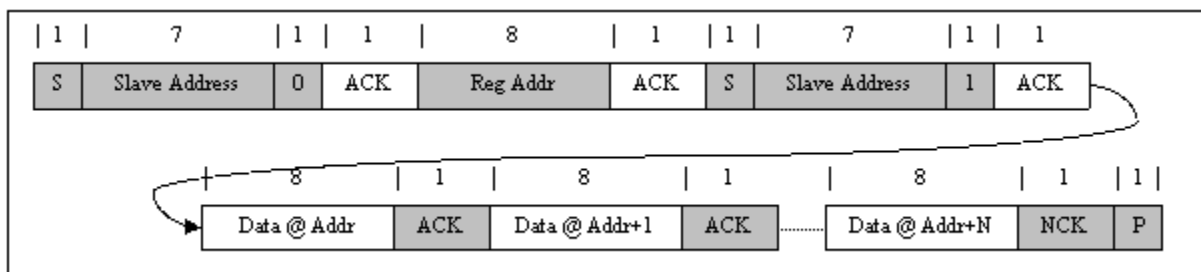
### 9.2.16.6 Single Read and Write


**图 23. Single Write**

**图 24. Single Read**

If the register address is not defined, the charger IC send back NACK and go back to the idle state.

### 9.2.16.7 Multi-Read and Multi-Write

The charger device supports multi-read and multi-write on REG00 through REG14 except REG0C.


**图 25. Multi-Write**

**图 26. Multi-Read**

REG0C is a fault register. It keeps all the fault information from last read until the host issues a new read. For example, if Charge Safety Timer Expiration fault occurs but recovers later, the fault register REG0C reports the fault when it is read the first time, but returns to normal when it is read the second time. In order to get the fault information at present, the host has to read REG0C for the second time. The only exception is NTC\_FAULT which always reports the actual condition on the TS pin. In addition, REG0C does not support multi-read and multi-write.

## 9.3 Device Functional Modes

### 9.3.1 Host Mode and Default Mode

The device is a host controlled charger, but it can operate in default mode without host management. In default mode, the device can be used as an autonomous charger with no host or while host is in sleep mode. When the charger is in default mode, WATCHDOG\_FAULT bit is HIGH. When the charger is in host mode, WATCHDOG\_FAULT bit is LOW.

After power-on-reset, the device starts in default mode with watchdog timer expired, or default mode. All the registers are in the default settings.

In default mode, the device keeps charging the battery with 12-hour fast charging safety timer. At the end of the 12-hour, the charging is stopped and the buck converter continues to operate to supply system load. Any write command to device transitions the charger from default mode to host mode. All the device parameters can be programmed by the host. To keep the device in host mode, the host has to reset the watchdog timer by writing 1 to WD\_RST bit before the watchdog timer expires (WATCHDOG\_FAULT bit is set), or disable watchdog timer by setting WATCHDOG bits=00.

When the watchdog timer (WATCHDOG\_FAULT bit = 1) is expired, the device returns to default mode and all registers are reset to default values except IINLIM, VINDPM, VINDPM\_OS, BATFET\_RST\_EN, BATFET\_DLY, and BATFET\_DIS bits.

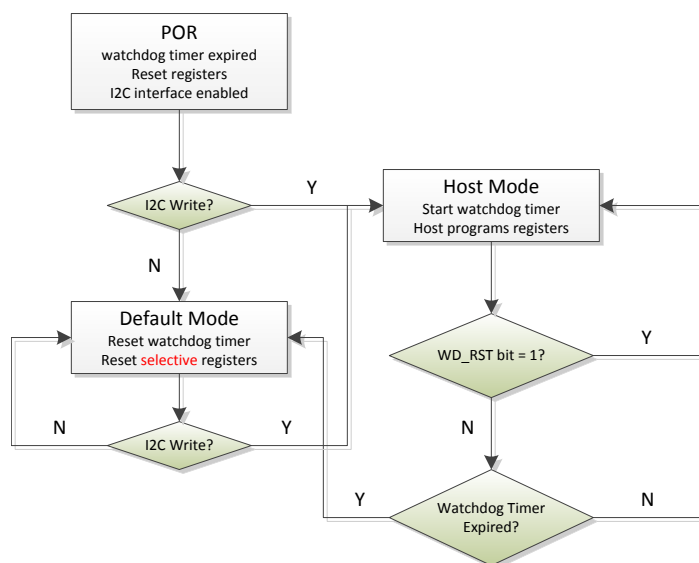


图 27. Watchdog Timer Flow Chart

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## 9.4 Register Map

I2C Slave Address: 6AH (1101010B + R/W) (bq25898D)

I2C Slave Address: 6BH (1101011B + R/W) (bq25898)

### 9.4.1 REG00

图 28. REG00

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 1   | 0   | 0   | 1   | 0   | 0   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 9. REG00

| Bit | Field     | Type | Reset                     | Description                                                                                                                                                                                                                                                                  |
|-----|-----------|------|---------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | EN_HIZ    | R/W  | by REG_RST<br>by Watchdog | Enable HIZ Mode<br>0 – Disable (default)<br>1 – Enable                                                                                                                                                                                                                       |
| 6   | EN_ILIM   | R/W  | by REG_RST<br>by Watchdog | Enable ILIM Pin<br>0 – Disable<br>1 – Enable (default: Enable ILIM pin (1))                                                                                                                                                                                                  |
| 5   | IINLIM[5] | R/W  | by REG_RST                | Input Current Limit bq25898D<br>USB Host SDP = 500mA<br>USB CDP = 1.5A<br>USB DCP = 3.25A<br>Adjustable High Voltage (MaxCharge) DCP = 1.5A<br>Unknown Adapter = 500mA<br>Non-Standard Adapter = 1A/2A/2.1A/2.4A<br>bq25898<br>PSEL= Hi (USB500) = 500mA<br>PSEL= Lo = 3.25A |
| 4   | IINLIM[4] | R/W  | by REG_RST                |                                                                                                                                                                                                                                                                              |
| 3   | IINLIM[3] | R/W  | by REG_RST                |                                                                                                                                                                                                                                                                              |
| 2   | IINLIM[2] | R/W  | by REG_RST                |                                                                                                                                                                                                                                                                              |
| 1   | IINLIM[1] | R/W  | by REG_RST                |                                                                                                                                                                                                                                                                              |
| 0   | IINLIM[0] | R/W  | by REG_RST                |                                                                                                                                                                                                                                                                              |

## 9.4.2 REG01

图 29. REG01

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 0   | 0   | 0   | 0   | 1   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 10. REG01

| Bit | Field         | Type | Reset       | Description                                                                                                                                                                        |
|-----|---------------|------|-------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | DPLUS_DAC[2]  | R/W  | by Software | D+ Output Driver (default 000)<br>000 – HiZ<br>001 – 0V<br>010 – 0.6V<br>011 – 1.2V<br>100 – 2.0V<br>101 – 2.7V<br>110 – 3.3V<br>111 – D+/D- Short (D+ and D- driver are disabled) |
| 6   | DPLUS_DAC[1]  | R/W  | by Software |                                                                                                                                                                                    |
| 5   | DPLUS_DAC[0]  | R/W  | by Software |                                                                                                                                                                                    |
| 4   | DMINUS_DAC[2] | R/W  | by Software |                                                                                                                                                                                    |
| 3   | DMINUS_DAC[1] | R/W  | by Software | D- Output Driver (default 000)<br>000 – HiZ<br>001 – 0V<br>010 – 0.6V<br>011 – 1.2V<br>100 – 2.0V<br>101 – 2.7V<br>110 or 111 – 3.3V                                               |
| 2   | DMINUS_DAC[0] | R/W  | by Software |                                                                                                                                                                                    |
| 1   | EN_12V        | R/W  | by Software |                                                                                                                                                                                    |
| 0   | VDPM_OS[0]    | R/W  | by Software |                                                                                                                                                                                    |

### 9.4.3 REG02

**图 30. REG02**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 1   | 1   | 1   | 0   | 1   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 11. REG02**

| Bit | Field        | Type | Reset                     | Description                                                                                                                                                                                                                   |
|-----|--------------|------|---------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | CONV_START   | R/W  | by REG_RST<br>by Watchdog | ADC Conversion Start Control<br>0 – ADC conversion not active (default).<br>1 – Start ADC Conversion<br>This bit is read-only when CONV_RATE = 1. The bit stays high during ADC conversion and during input source detection. |
| 6   | CONV_RATE    | R/W  | by REG_RST<br>by Watchdog | ADC Conversion Rate Selection<br>0 – One shot ADC conversion (default)<br>1 – Start 1s Continuous Conversion                                                                                                                  |
| 5   | BOOST_FREQ   | R/W  | by REG_RST<br>by Watchdog | Boost Mode Frequency Selection<br>0 – 1.5MHz (default)<br>1 – 500KHz<br>Note: Write to this bit is ignored when OTG_CONFIG is enabled.                                                                                        |
| 4   | ICO_EN       | R/W  | by REG_RST                | Input Current Optimizer (ICO) Enable<br>0 – Disable ICO Algorithm<br>1 – Enable ICO Algorithm (default)                                                                                                                       |
| 3   | HVDCP_EN     | R/W  | by REG_RST                | High Voltage DCP Enable (bq25898D only)<br>0 – Disable HVDCP handshake<br>1 – Enable HVDCP handshake (default)                                                                                                                |
| 2   | MAXC_EN      | R/W  | by REG_RST                | MaxCharge Adapter Enable (bq25898D only)<br>0 – Disable MaxCharge handshake<br>1 – Enable MaxCharge handshake (default)                                                                                                       |
| 1   | FORCE_DPDM   | R/W  | by REG_RST<br>by Watchdog | Force D+/D- Detection<br>0 – Not in D+/D- or PSEL detection (default)<br>1 – Force D+/D- detection                                                                                                                            |
| 0   | AUTO_DPDM_EN | R/W  | by REG_RST                | Automatic D+/D- Detection Enable<br>0 –Disable D+/D- or PSEL detection when VBUS is plugged-in<br>1 –Enable D+/D- or PEL detection when VBUS is plugged-in (default)                                                          |

## 9.4.4 REG03

图 31. REG03

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 1   | 1   | 0   | 1   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 12. REG03

| Bit                                 | Field                      | Type | Reset                      | Description                                                                                                                                                                                                                                                                                                                                                                                             |
|-------------------------------------|----------------------------|------|----------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7                                   | VOK_OTG_EN (bq25898 only)  | R/W  | by Software                | 0 – Disabled, VOK = 0<br>(default)<br>1 – Enabled, VOK = 1<br><br>1. Adapter Plug-in VOK_OTG_EN = x and VOK = 1<br>2. OTG if VOK_OTG_EN = 1 ≥ VOK = 1 if VOK_OTG_EN = 0 ≥ VOK = 0<br>3. Battery Only (non-OTG) VOK_OTG_EN = x and VOK = 0                                                                                                                                                               |
|                                     | FORCE_DSEL (bq25898D only) | R/W  | by Software                | 0 – Allow DSEL = 0 (default)<br>1 – Force DSEL = 1<br><br>1. Adaptor Plug-in DSEL= 1 when:<br>1) During AUTO_DPDM, FORCE_DPDM, DCP, HVDSP, MaxCharge and FORCE_DSEL = x or<br>2) Other input source and FORCE_DSEL = 1 DSEL = 0 when other input source and FORCE_DSEL = 0<br>2. OTG if FORCE_DSEL = 1 ≥ DSEL = 1 if FORCE_DSEL = 0 ≥ DSEL = 0<br>3. Battery only (non-OTG) DSEL = 0 and FORCE_DSEL = x |
| 6                                   | WD_RST                     | R/W  | by Software<br>by Watchdog | I2C Watchdog Timer Reset<br>0 – Normal (default)<br>1 – Reset (Back to 0 after timer reset)                                                                                                                                                                                                                                                                                                             |
| <b>Charger Configuration</b>        |                            |      |                            |                                                                                                                                                                                                                                                                                                                                                                                                         |
| 5                                   | OTG_CONFIG                 | R/W  | by REG_RST<br>by Watchdog  | Boost (OTG) Mode Configuration<br>0 – OTG Disable (default)<br>1 – OTG Enable                                                                                                                                                                                                                                                                                                                           |
| 4                                   | CHG_CONFIG                 | R/W  | by REG_RST<br>by Watchdog  | Charge Enable Configuration<br>0 - Charge Disable<br>1- Charge Enable (default)                                                                                                                                                                                                                                                                                                                         |
| <b>Minimum System Voltage Limit</b> |                            |      |                            |                                                                                                                                                                                                                                                                                                                                                                                                         |
| 3                                   | SYS_MIN[2]                 | R/W  | by REG_RST                 | 0.4V                                                                                                                                                                                                                                                                                                                                                                                                    |
| 2                                   | SYS_MIN[1]                 | R/W  | by REG_RST                 | 0.2V                                                                                                                                                                                                                                                                                                                                                                                                    |
| 1                                   | SYS_MIN[0]                 | R/W  | by REG_RST                 | 0.1V                                                                                                                                                                                                                                                                                                                                                                                                    |
| 0                                   | MIN_VBAT_SEL               | R/W  | by REG_RST                 | 0 – 2.9V BAT falling (default = 0)<br>1 – 2.5V BAT falling                                                                                                                                                                                                                                                                                                                                              |

### 9.4.5 REG04

**图 32. REG04**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 1   | 0   | 0   | 0   | 0   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 13. REG04**

| Bit | Field    | Type | Reset                     | Description                                                                                                                            |
|-----|----------|------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------|
| 7   | EN_PUMPX | R/W  | by REG_RST<br>by Watchdog | Current pulse control Enable<br>0 - Disable Current pulse control (default)<br>1- Enable Current pulse control (PUMPX_UP and PUMPX_DN) |
| 6   | ICHG[6]  | R/W  | by REG_RST<br>by Watchdog | 4096mA                                                                                                                                 |
| 5   | ICHG[5]  | R/W  | by REG_RST<br>by Watchdog | 2048mA                                                                                                                                 |
| 4   | ICHG[4]  | R/W  | by REG_RST<br>by Watchdog | 1024mA                                                                                                                                 |
| 3   | ICHG[3]  | R/W  | by REG_RST<br>by Watchdog | 512mA                                                                                                                                  |
| 2   | ICHG[2]  | R/W  | by REG_RST<br>by Watchdog | 256mA                                                                                                                                  |
| 1   | ICHG[1]  | R/W  | by REG_RST<br>by Watchdog | 128mA                                                                                                                                  |
| 0   | ICHG[0]  | R/W  | by REG_RST<br>by Watchdog | 64mA                                                                                                                                   |

## 9.4.6 REG05

**图 33. REG05**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 1   | 0   | 0   | 1   | 1   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 14. REG05**

| Bit | Field      | Type | Reset                     | Description |
|-----|------------|------|---------------------------|-------------|
| 7   | IPRECHG[3] | R/W  | by REG_RST<br>by Watchdog | 512mA       |
| 6   | IPRECHG[2] | R/W  | by REG_RST<br>by Watchdog | 256mA       |
| 5   | IPRECHG[1] | R/W  | by REG_RST<br>by Watchdog | 128mA       |
| 4   | IPRECHG[0] | R/W  | by REG_RST<br>by Watchdog | 64mA        |
| 3   | ITERM[3]   | R/W  | by REG_RST<br>by Watchdog | 512mA       |
| 2   | ITERM[2]   | R/W  | by REG_RST<br>by Watchdog | 256mA       |
| 1   | ITERM[1]   | R/W  | by REG_RST<br>by Watchdog | 128mA       |
| 0   | ITERM[0]   | R/W  | by REG_RST<br>by Watchdog | 64mA        |



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**9.4.7 REG06**
**图 34. REG06**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 1   | 0   | 1   | 1   | 1   | 1   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 15. REG06**

| Bit | Field   | Type | Reset                     | Description                                                                                                                                                                           |
|-----|---------|------|---------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | VREG[5] | R/W  | by REG_RST<br>by Watchdog | 512mV                                                                                                                                                                                 |
| 6   | VREG[4] | R/W  | by REG_RST<br>by Watchdog | 256mV                                                                                                                                                                                 |
| 5   | VREG[3] | R/W  | by REG_RST<br>by Watchdog | 128mV                                                                                                                                                                                 |
| 4   | VREG[2] | R/W  | by REG_RST<br>by Watchdog | 64mV                                                                                                                                                                                  |
| 3   | VREG[1] | R/W  | by REG_RST<br>by Watchdog | 32mV                                                                                                                                                                                  |
| 2   | VREG[0] | R/W  | by REG_RST<br>by Watchdog | 16mV                                                                                                                                                                                  |
| 1   | BATLOWV | R/W  | by REG_RST<br>by Watchdog | Battery Precharge to Fast Charge Threshold<br>0 – 2.8V<br>1 – 3.0V (default)                                                                                                          |
| 0   | VRECHG  | R/W  | by REG_RST<br>by Watchdog | Battery Recharge Threshold Offset<br>(below Charge Voltage Limit)<br>0 – 100mV ( $V_{RECHG}$ ) below VREG (REG06[7:2]) (default)<br>1 – 200mV ( $V_{RECHG}$ ) below VREG (REG06[7:2]) |

### 9.4.8 REG07

**图 35. REG07**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 1   | 0   | 0   | 1   | 1   | 1   | 0   | 1   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 16. REG07**

| Bit | Field               | Type | Reset                     | Description                                                                                                     |
|-----|---------------------|------|---------------------------|-----------------------------------------------------------------------------------------------------------------|
| 7   | EN_TERM             | R/W  | by REG_RST<br>by Watchdog | Charging Termination Enable<br>0 – Disable<br>1 – Enable (default)                                              |
| 6   | STAT_DIS            | R/W  | by REG_RST<br>by Watchdog | STAT Pin Disable<br>0 – Enable STAT pin function (default)<br>1 – Disable STAT pin function                     |
| 5   | WATCHDOG[1]         | R/W  | by REG_RST<br>by Watchdog | I2C Watchdog Timer Setting<br>00 – Disable watchdog timer<br>01 – 40s (default)<br>10 – 80s<br>11 – 160s        |
| 4   | WATCHDOG[0]         | R/W  | by REG_RST<br>by Watchdog |                                                                                                                 |
| 3   | EN_TIMER            | R/W  | by REG_RST<br>by Watchdog | Charging Safety Timer Enable<br>0 – Disable<br>1 – Enable (default)                                             |
| 2   | CHG_TIMER[1]        | R/W  | by REG_RST<br>by Watchdog | Fast Charge Timer Setting<br>00 – 5 hrs<br>01 – 8 hrs<br>10 – 12 hrs (default)<br>11 – 20 hrs                   |
| 1   | CHG_TIMER[0]        | R/W  | by REG_RST<br>by Watchdog |                                                                                                                 |
| 0   | JEITA_ISET (0C-10C) | R/W  | by REG_RST<br>by Watchdog | JEITA Low Temperature Current Setting<br>0 – 50% of ICHG (REG04[6:0])<br>1 – 20% of ICHG (REG04[6:0]) (default) |

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**9.4.9 REG08**
**图 36. REG08**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 0   | 0   | 0   | 1   | 1   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 17. REG08**

| Bit | Field       | Type | Reset                     | Description                                                                                  |
|-----|-------------|------|---------------------------|----------------------------------------------------------------------------------------------|
| 7   | BAT_COMP[2] | R/W  | by REG_RST<br>by Watchdog | 80mΩ                                                                                         |
| 6   | BAT_COMP[1] | R/W  | by REG_RST<br>by Watchdog | 40mΩ                                                                                         |
| 5   | BAT_COMP[0] | R/W  | by REG_RST<br>by Watchdog | 20mΩ                                                                                         |
| 4   | VCLAMP[2]   | R/W  | by REG_RST<br>by Watchdog | 128mV                                                                                        |
| 3   | VCLAMP[1]   | R/W  | by REG_RST<br>by Watchdog | 64mV                                                                                         |
| 2   | VCLAMP[0]   | R/W  | by REG_RST<br>by Watchdog | 32mV                                                                                         |
| 1   | TREG[1]     | R/W  | by REG_RST<br>by Watchdog | Thermal Regulation Threshold<br>00 – 60°C<br>01 – 80°C<br>10 – 100°C<br>11 – 120°C (default) |
| 0   | TREG[0]     | R/W  | by REG_RST<br>by Watchdog |                                                                                              |

## 9.4.10 REG09

图 37. REG09

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 1   | 0   | 0   | 0   | 1   | 0   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 18. REG09

| Bit | Field                | Type | Reset                     | Description                                                                                                                                                                                                          |
|-----|----------------------|------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | FORCE_ICO            | R/W  | by REG_RST<br>by Watchdog | Force Start Input Current Optimizer (ICO)<br>0 – Do not force ICO (default)<br>1 – Force ICO<br>Note:<br>This bit is can only be set only and always returns to 0 after ICO starts                                   |
| 6   | TMR2X_EN             | R/W  | by REG_RST<br>by Watchdog | Safety Timer Setting during DPM or Thermal Regulation<br>0 – Safety timer not slowed by 2X during input DPM or thermal regulation<br>1 – Safety timer slowed by 2X during input DPM or thermal regulation (default)  |
| 5   | BATFET_DIS           | R/W  | by REG_RST                | Force BATFET off to enable ship mode with $t_{SM\_DLY}$ delay time<br>0 – Allow BATFET turn on (default)<br>1 – Force BATFET off                                                                                     |
| 4   | JEITA_VSET (45C-60C) | R/W  | by REG_RST<br>by Watchdog | JEITA High Temperature Voltage Setting<br>0 – Set Charge Voltage to VREG-200mV during JEITA hig temperature (default)<br>1 – Set Charge Voltage to VREG during JEITA high temperature                                |
| 3   | BATFET_DLY           | R/W  | by REG_RST                | BATFET turn off delay control<br>0 – BATFET turn off immediately when BATFET_DIS bit is set (default)<br>1 – BATFET turn off delay by $t_{SM\_DLY}$ when BATFET_DIS bit is set                                       |
| 2   | BATFET_RST_EN        | R/W  | by REG_RST                | BATFET full system reset enable<br>0 – Disable BATFET full system reset<br>1 – Enable BATFET full system reset (default)                                                                                             |
| 1   | PUMPX_UP             | R/W  | by REG_RST<br>by Watchdog | Current pulse control voltage up enable<br>0 – Disable (default)<br>1 – Enable<br>Note:<br>This bit is can only be set when EN_PUMPX bit is set and returns to 0 after current pulse control sequence is completed   |
| 0   | PUMPX_DN             | R/W  | by REG_RST<br>by Watchdog | Current pulse control voltage down enable<br>0 – Disable (default)<br>1 – Enable<br>Note:<br>This bit is can only be set when EN_PUMPX bit is set and returns to 0 after current pulse control sequence is completed |

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**9.4.11 REG0A**
**图 38. REG0A**

|     |     |     |     |     |     |     |     |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
| 0   | 1   | 1   | 1   | 0   | 1   | 0   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 19. REG0A**

| Bit                        | Field        | Type | Reset                     | Description                                                   |
|----------------------------|--------------|------|---------------------------|---------------------------------------------------------------|
| 7                          | BOOSTV[3]    | R/W  | by REG_RST<br>by Watchdog | 512mV                                                         |
| 6                          | BOOSTV[2]    | R/W  | by REG_RST<br>by Watchdog | 256mV                                                         |
| 5                          | BOOSTV[1]    | R/W  | by REG_RST<br>by Watchdog | 128mV                                                         |
| 4                          | BOOSTV[0]    | R/W  | by REG_RST<br>by Watchdog | 64mV                                                          |
| 3                          | PFM_OTG_DIS  | R/W  | by REG_RST                | 0 – Enable (default = 0)<br>1 – Disable                       |
| <b>Boost Current Limit</b> |              |      |                           |                                                               |
| 2                          | BOOST_LIM[2] | R/W  | by REG_RST<br>by Watchdog | 000: 0.5A<br>001: 0.8A<br>010: 1.0A<br>011: 1.2A<br>100: 1.5A |
| 1                          | BOOST_LIM[1] | R/W  | by REG_RST<br>by Watchdog | 101: 1.8A<br>110: 2.1A<br>111: 2.4A                           |
| 0                          | BOOST_LIM[0] | R/W  | by REG_RST<br>by Watchdog |                                                               |

### 9.4.12 REG0B

**图 39. REG0B**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| x | x | x | x | x | x | x | x |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 20. REG0B**

| Bit | Field        | Type | Reset | Description                                                                                                                                                                                                                                                                                                                                                                                                              |
|-----|--------------|------|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | VBUS_STAT[2] | R    | N/A   | VBUS Status register<br>bq25898D<br>000: No Input 001: USB Host SDP<br>010: USB CDP (1.5A)<br>011: USB DCP (3.25A)<br>100: Adjustable High Voltage DCP (MaxCharge) (1.5A)<br>101: Unknown Adapter (500mA)<br>110: Non-Standard Adapter (1A/2A/2.1A/2.4A)<br>111: OTG<br>bq25898<br>000: No Input<br>001: USB Host SDP<br>010: Adapter (3.25A)<br>111: OTG<br>Note: Software current limit is reported in IINLIM register |
| 6   | VBUS_STAT[1] | R    | N/A   |                                                                                                                                                                                                                                                                                                                                                                                                                          |
| 5   | VBUS_STAT[0] | R    | N/A   |                                                                                                                                                                                                                                                                                                                                                                                                                          |
| 4   | CHRG_STAT[1] | R    | N/A   | Charging Status<br>00 – Not Charging<br>01 – Pre-charge ( $< V_{BATLOWV}$ )<br>10 – Fast Charging<br>11 – Charge Termination Done                                                                                                                                                                                                                                                                                        |
| 3   | CHRG_STAT[0] | R    | N/A   |                                                                                                                                                                                                                                                                                                                                                                                                                          |
| 2   | PG_STAT      | R    | N/A   | Power Good Status<br>0 – Not Power Good<br>1 – Power Good                                                                                                                                                                                                                                                                                                                                                                |
| 1   | Reserved     | R    | N/A   | Reserved: Always reads 1                                                                                                                                                                                                                                                                                                                                                                                                 |
| 0   | VSYS_STAT    | R    | N/A   | VSYS Regulation Status<br>0 – Not in VSYSMIN regulation ( $BAT > VSYSMIN$ )<br>1 – In VSYSMIN regulation ( $BAT < VSYSMIN$ )                                                                                                                                                                                                                                                                                             |

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**9.4.13 REG0C**
**图 40. REG0C**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| x | x | x | x | x | x | x | x |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 21. REG0C**

| Bit | Field          | Type | Reset | Description                                                                                                                                                                       |
|-----|----------------|------|-------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | WATCHDOG_FAULT | R    | N/A   | Watchdog Fault Status<br>Status 0 – Normal<br>1- Watchdog timer expiration                                                                                                        |
| 6   | BOOST_FAULT    | R    | N/A   | Boost Mode Fault Status<br>0 – Normal<br>1 – VBUS overloaded in OTG, or VBUS OVP, or battery is too low in boost mode                                                             |
| 5   | CHRG_FAULT[1]  | R    | N/A   | Charge Fault Status<br>00 – Normal                                                                                                                                                |
| 4   | CHRG_FAULT[0]  | R    | N/A   | 01 – Input fault ( $V_{BUS} > V_{ACOV}$ or $V_{BAT} < V_{BUS} < V_{VBUSMIN}$ (typical 3.8V)<br>10 - Thermal shutdown<br>11 – Charge Safety Timer Expiration                       |
| 3   | BAT_FAULT      | R    | N/A   | Battery Fault Status<br>0 – Normal<br>1 – BATOV (V <sub>BAT</sub> > V <sub>BATOV</sub> )                                                                                          |
| 2   | NTC_FAULT[2]   | R    | N/A   | NTC Fault Status<br>Buck Mode:<br>000 – Normal<br>010 – TS Warm<br>011 – TS Cool<br>101 – TS Cold<br>110 – TS Hot<br>Boost Mode:<br>000 – Normal<br>101 – TS Cold<br>110 – TS Hot |
| 1   | NTC_FAULT[1]   | R    | N/A   |                                                                                                                                                                                   |
| 0   | NTC_FAULT[0]   | R    | N/A   |                                                                                                                                                                                   |

#### 9.4.14 REG0D

**图 41. REG0D**

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| 0   | 0   | 0   | 1   | 0   | 0   | 1   | 0   |
| R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 22. REG0D**

| Bit | Field        | Type | Reset      | Description                                                                                                         |
|-----|--------------|------|------------|---------------------------------------------------------------------------------------------------------------------|
| 7   | FORCE_VINDPM | R/W  | by REG_RST | VINDPM Threshold Setting Method<br>0 – Run Relative VINDPM Threshold (default)<br>1 – Run Absolute VINDPM Threshold |
| 6   | VINDPM[6]    | R/W  | by REG_RST | 6400mV                                                                                                              |
| 5   | VINDPM[5]    | R/W  | by REG_RST | 3200mV                                                                                                              |
| 4   | VINDPM[4]    | R/W  | by REG_RST | 1600mV                                                                                                              |
| 3   | VINDPM[3]    | R/W  | by REG_RST | 800mV                                                                                                               |
| 2   | VINDPM[2]    | R/W  | by REG_RST | 400mV                                                                                                               |
| 1   | VINDPM[1]    | R/W  | by REG_RST | 200mV                                                                                                               |
| 0   | VINDPM[0]    | R/W  | by REG_RST | 100mV                                                                                                               |

#### 9.4.15 REG0E

**图 42. REG0E**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 23. REG0E**

| Bit | Field      | Type | Reset | Description                                                          |
|-----|------------|------|-------|----------------------------------------------------------------------|
| 7   | THERM_STAT | R    | N/A   | Thermal Regulation Status<br>0 – Normal<br>1 – In Thermal Regulation |
| 6   | BATV[6]    | R    | N/A   | 1280mV                                                               |
| 5   | BATV[5]    | R    | N/A   | 640mV                                                                |
| 4   | BATV[4]    | R    | N/A   | 320mV                                                                |
| 3   | BATV[3]    | R    | N/A   | 160mV                                                                |
| 2   | BATV[2]    | R    | N/A   | 80mV                                                                 |
| 1   | BATV[1]    | R    | N/A   | 40mV                                                                 |
| 0   | BATV[0]    | R    | N/A   | 20mV                                                                 |



## 9.4.16 REG0F

**图 43. REG0F**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 24. REG0F**

| Bit | Field    | Type | Reset | Description              |
|-----|----------|------|-------|--------------------------|
| 7   | Reserved | R    | N/A   | Reserved: Always reads 0 |
| 6   | SYSV[6]  | R    | N/A   | 1280mV                   |
| 5   | SYSV[5]  | R    | N/A   | 640mV                    |
| 4   | SYSV[4]  | R    | N/A   | 320mV                    |
| 3   | SYSV[3]  | R    | N/A   | 160mV                    |
| 2   | SYSV[2]  | R    | N/A   | 80mV                     |
| 1   | SYSV[1]  | R    | N/A   | 40mV                     |
| 0   | SYSV[0]  | R    | N/A   | 20mV                     |

ADC conversion of System Voltage ( $V_{SYS}$ )  
Offset: 2.304V  
Range: 2.304V (0000000) – 4.848V (1111111)  
Default: 2.304V (0000000)

## 9.4.17 REG10

**图 44. REG10**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 25. REG10**

| Bit | Field    | Type | Reset | Description              |
|-----|----------|------|-------|--------------------------|
| 7   | Reserved | R    | N/A   | Reserved: Always reads 0 |
| 6   | TSPCT[6] | R    | N/A   | 29.76%                   |
| 5   | TSPCT[5] | R    | N/A   | 14.88%                   |
| 4   | TSPCT[4] | R    | N/A   | 7.44%                    |
| 3   | TSPCT[3] | R    | N/A   | 3.72%                    |
| 2   | TSPCT[2] | R    | N/A   | 1.86%                    |
| 1   | TSPCT[1] | R    | N/A   | 0.93%                    |
| 0   | TSPCT[0] | R    | N/A   | 0.465%                   |

ADC conversion of TS Voltage (TS) as percentage of REGN  
Offset: 21%  
Range 21% (0000000) – 80% (1111111)  
Default: 21% (0000000)

### 9.4.18 REG11

图 45. REG11

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 26. REG11

| Bit | Field    | Type | Reset | Description                                                    |
|-----|----------|------|-------|----------------------------------------------------------------|
| 7   | VBUS_GD  | R    | N/A   | VBUS Good Status<br>0 – Not VBUS attached<br>1 – VBUS Attached |
| 6   | VBUSV[6] | R    | N/A   | 6400mV                                                         |
| 5   | VBUSV[5] | R    | N/A   | 3200mV                                                         |
| 4   | VBUSV[4] | R    | N/A   | 1600mV                                                         |
| 3   | VBUSV[3] | R    | N/A   | 800mV                                                          |
| 2   | VBUSV[2] | R    | N/A   | 400mV                                                          |
| 1   | VBUSV[1] | R    | N/A   | 200mV                                                          |
| 0   | VBUSV[0] | R    | N/A   | 100mV                                                          |

ADC conversion of VBUS voltage ( $V_{BUS}$ )  
Offset: 2.6V  
Range 2.6V (0000000) – 15.3V (1111111)  
Default: 2.6V (0000000)

### 9.4.19 REG12

图 46. REG12

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 27. REG12

| Bit | Field    | Type | Reset | Description    |
|-----|----------|------|-------|----------------|
| 7   | Unused   | R    | N/A   | Always reads 0 |
| 6   | ICHGR[6] | R    | N/A   | 3200mA         |
| 5   | ICHGR[5] | R    | N/A   | 1600mA         |
| 4   | ICHGR[4] | R    | N/A   | 800mA          |
| 3   | ICHGR[3] | R    | N/A   | 400mA          |
| 2   | ICHGR[2] | R    | N/A   | 200mA          |
| 1   | ICHGR[1] | R    | N/A   | 100mA          |
| 0   | ICHGR[0] | R    | N/A   | 50mA           |

ADC conversion of Charge Current ( $I_{BAT}$ ) when  $V_{BAT} > V_{BATSHORT}$   
Offset: 0mA  
Range 0mA (0000000) – 6350mA (1111111)  
Default: 0mA (0000000)  
Note:  
This register returns 0000000 for  $V_{BAT} < V_{BATSHORT}$

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**9.4.20 REG13**
**图 47. REG13**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| R | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 28. REG13**

| Bit | Field       | Type | Reset | Description                                      |
|-----|-------------|------|-------|--------------------------------------------------|
| 7   | VDPM_STAT   | R    | N/A   | VINDPM Status<br>0 – Not in VINDPM<br>1 – VINDPM |
| 6   | IDPM_STAT   | R    | N/A   | IINDPM Status<br>0 – Not in IINDPM<br>1 – IINDPM |
| 5   | IDPM_LIM[5] | R    | N/A   | 1600mA                                           |
| 4   | IDPM_LIM[4] | R    | N/A   | 800mA                                            |
| 3   | IDPM_LIM[3] | R    | N/A   | 400mA                                            |
| 2   | IDPM_LIM[2] | R    | N/A   | 200mA                                            |
| 1   | IDPM_LIM[1] | R    | N/A   | 100mA                                            |
| 0   | IDPM_LIM[0] | R    | N/A   | 50mA                                             |

Input Current Limit in effect while Input Current Optimizer (ICO) is enabled  
Offset: 100mA (default)  
Range 100mA (0000000) – 3.25mA (1111111)

**9.4.21 REG14**
**图 48. REG14**

| 7   | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| 0   | 0 | X | X | X | 1 | 0 | 1 |
| R/W | R | R | R | R | R | R | R |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 29. REG14**

| Bit | Field         | Type | Reset | Description                                                                                                                                                                          |
|-----|---------------|------|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 7   | REG_RST       | R/W  | N/A   | Register Reset<br>0 – Keep current register setting (default)<br>1 – Reset to default register value and reset safety timer<br>Note:<br>Reset to 0 after register reset is completed |
| 6   | ICO_OPTIMIZED | R    | N/A   | Input Current Optimizer (ICO) Status<br>0 – Optimization is in progress<br>1 – Maximum Input Current Detected                                                                        |
| 5   | PN[2]         | R    | N/A   | Device Configuration<br>010: bq25898D<br>000: bq25898                                                                                                                                |
| 4   | PN[1]         | R    | N/A   |                                                                                                                                                                                      |
| 3   | PN[0]         | R    | N/A   |                                                                                                                                                                                      |
| 2   | TS_PROFILE    | R    | N/A   | Temperature Profile<br>1- JEITA (default)                                                                                                                                            |
| 1   | DEV_REV[1]    | R    | N/A   | Device Revision: 01                                                                                                                                                                  |
| 0   | DEV_REV[0]    | R    | N/A   |                                                                                                                                                                                      |

## 10 Application and Implementation

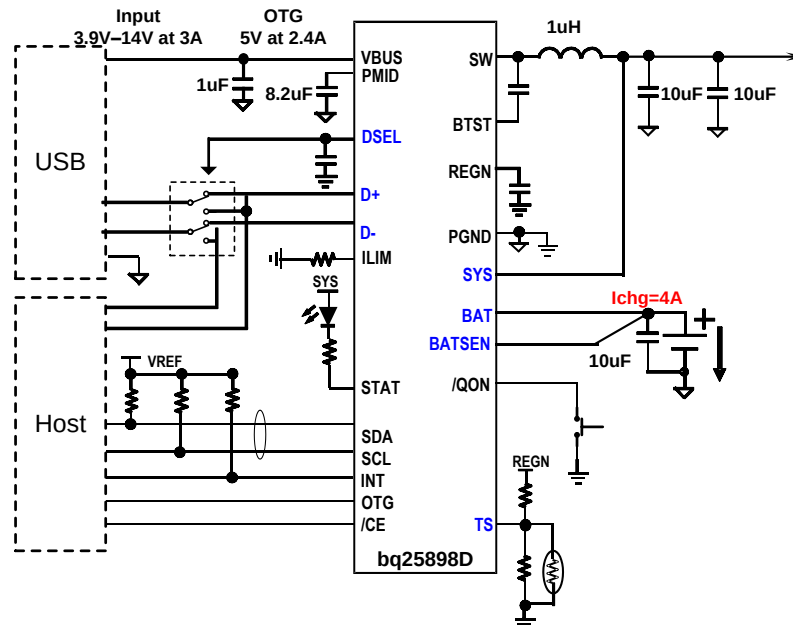
### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

A typical application consists of the device configured as an I<sup>2</sup>C controlled power path management device and a single cell battery charger for Li-Ion and Li-polymer batteries used in a wide range of smartphones and other portable devices. It integrates an input reverse-block FET (RBFET, Q1), high-side switching FET (HSFET, Q2), low-side switching FET (LSFET, Q3), and BATFET (Q4) between the system and battery. The device also integrates a bootstrap diode for the high-side gate drive.

### 10.2 Typical Application Diagram



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VREF is the pull up voltage of I2C communication interface

图 49. bq25898D Application Diagram with PSEL with Interface and USB On-The-Go (OTG)

#### 10.2.1 Design Requirements

For this design example, use the parameters shown in 表 30.

表 30. Design Parameters

| PARAMETER           | VALUE         |
|---------------------|---------------|
| Input voltage range | 3.9 V to 14 V |
| Input current limit | 1.5 A         |
| Fast charge current | 4032 mA       |
| Output voltage      | 4.208 V       |

## 10.2.2 Detailed Design Procedure

### 10.2.2.1 Inductor Selection

The device has 1.5 MHz switching frequency to allow the use of small inductor and capacitor values. The Inductor saturation current should be higher than the charging current ( $I_{CHG}$ ) plus half the ripple current ( $I_{RIPPLE}$ ):

$$I_{BAT} \geq I_{CHG} + (1/2) I_{RIPPLE} \quad (5)$$

The inductor ripple current depends on input voltage ( $V_{BUS}$ ), duty cycle ( $D = V_{BAT}/V_{BUS}$ ), switching frequency ( $f_s$ ) and inductance ( $L$ ):

$$I_{RIPPLE} = \frac{V_{BUS} \times D \times (1-D)}{f_s \times L} \quad (6)$$

The maximum inductor ripple current happens with  $D = 0.5$  or close to 0.5. Usually inductor ripple is designed in the range of (20–40%) maximum charging current as a trade-off between inductor size and efficiency for a practical design.

### 10.2.2.2 Buck Input Capacitor

Input capacitor should have enough ripple current rating to absorb input switching ripple current. The worst case RMS ripple current is half of the charging current when duty cycle is 0.5. If the converter does not operate at 50% duty cycle, then the worst case capacitor RMS current  $I_{PMID}$  occurs where the duty cycle is closest to 50% and can be estimated by 公式 7:

$$I_{PMID} = I_{CHG} \times \sqrt{D \times (1-D)} \quad (7)$$

Low ESR ceramic capacitor such as X7R or X5R is preferred for input decoupling capacitor and should be placed to the drain of the high side MOSFET and source of the low side MOSFET as close as possible. Voltage rating of the capacitor must be higher than normal input voltage level. 25 V rating or higher capacitor is preferred for up to 14-V input voltage. 8.2- $\mu$ F capacitance is suggested for typical of 3 A – 5 A charging current.

### 10.2.2.3 System Output Capacitor

Output capacitor also should have enough ripple current rating to absorb output switching ripple current. The output capacitor RMS current  $I_{COUT}$  is given:

$$I_{CSYS} = \frac{I_{RIPPLE}}{2 \times \sqrt{3}} \approx 0.29 \times I_{RIPPLE} \quad (8)$$

The output capacitor voltage ripple can be calculated as follows:

$$\Delta V_O = \frac{V_{SYS}}{8 LC_{SYS} f_s^2} \left( 1 - \frac{V_{SYS}}{V_{BUS}} \right) \quad (9)$$

At certain input/output voltage and switching frequency, the voltage ripple can be reduced by increasing the output filter LC. The charger device has internal loop compensator. To get good loop stability, 1- $\mu$ H and minimum of 20- $\mu$ F output capacitor is recommended. The preferred ceramic capacitor is 6V or higher rating, X7R or X5R.

### 10.2.3 Application Curves

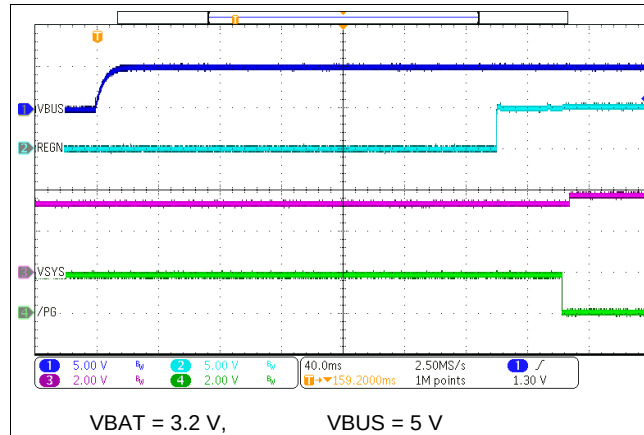


图 50. Power Up with Charge Disabled

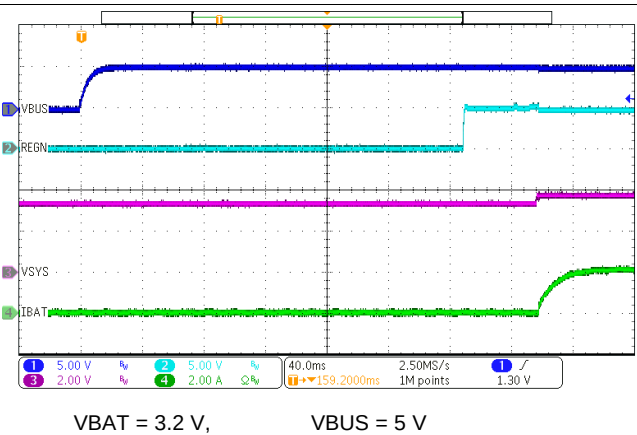


图 51. Power Up with Charge Enabled

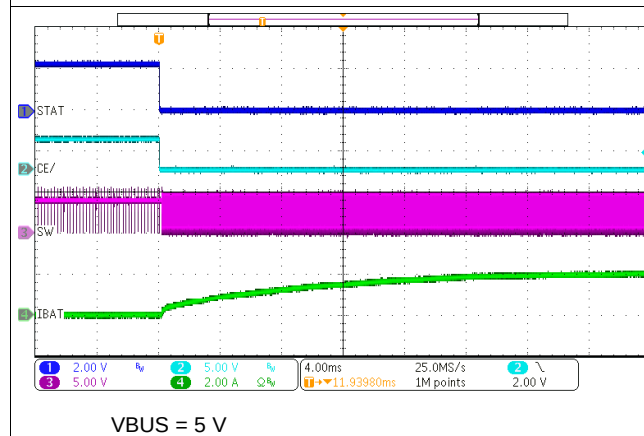


图 52. Charge Enable

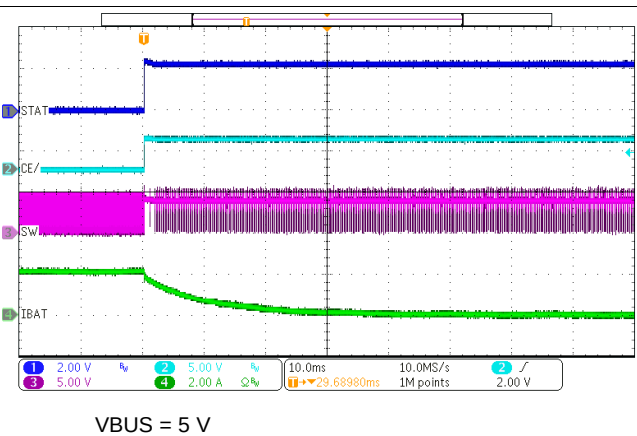


图 53. Charge Disable

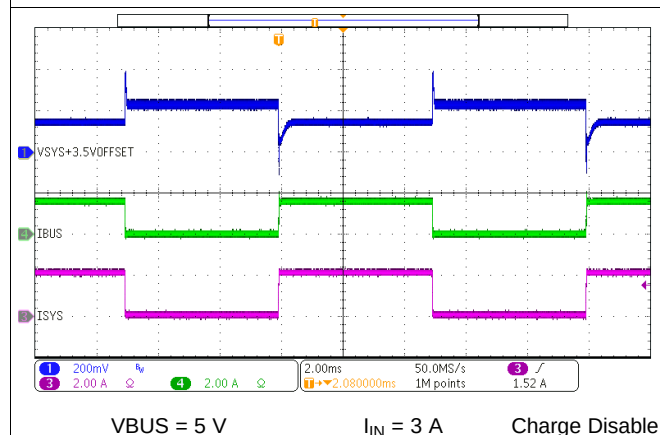


图 54. Input Current DPM Response without Battery

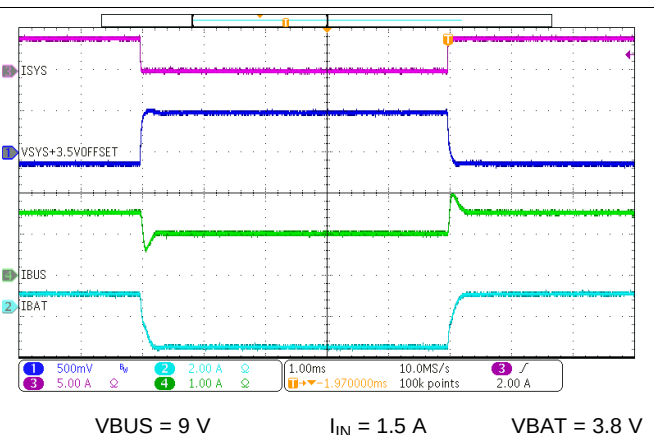


图 55. Load Transient During Supplement Mode

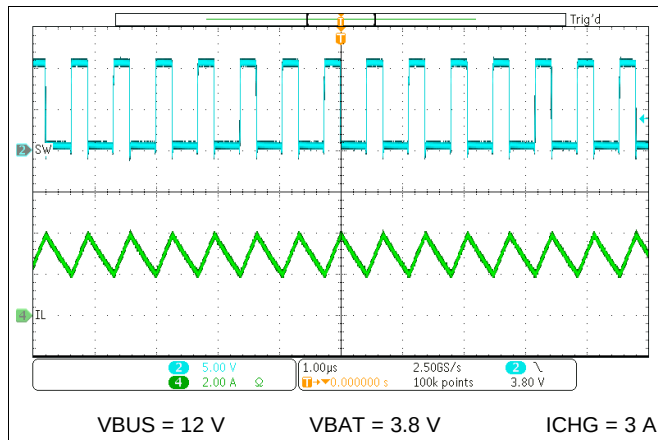


图 56. PWM Switching Waveform

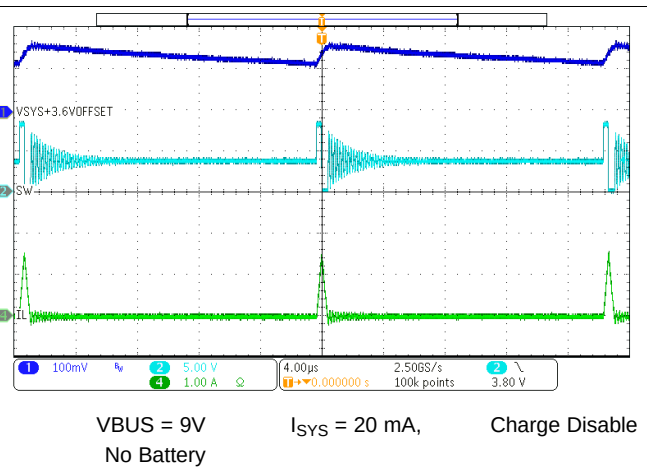


图 57. PFM Switching Waveform

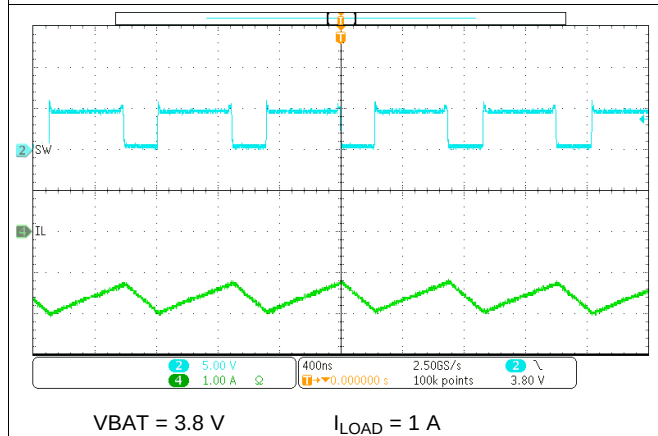


图 58. Boost Mode Switching Waveform

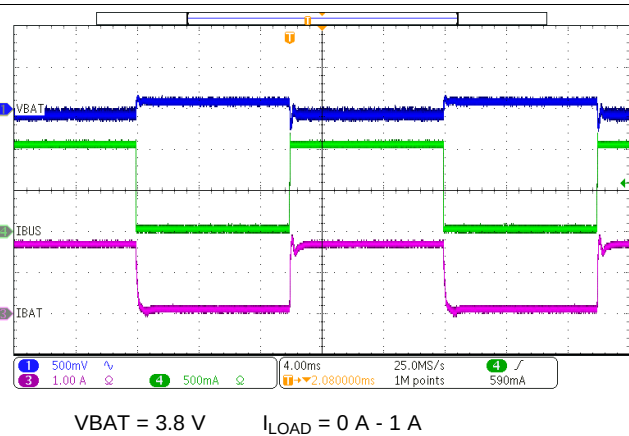


图 59. Boost Mode Load Transient

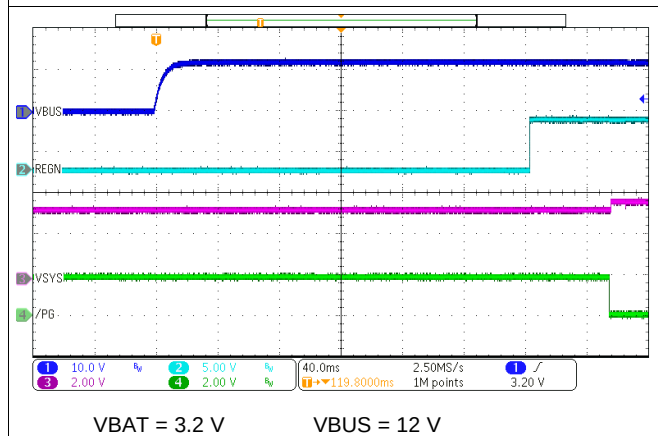


图 60. Power Up with Charge Disabled

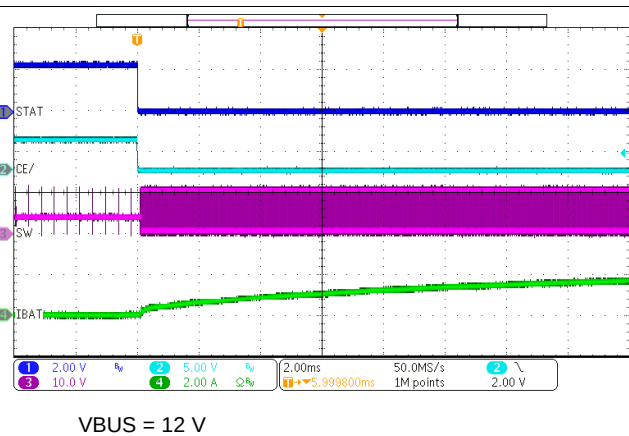
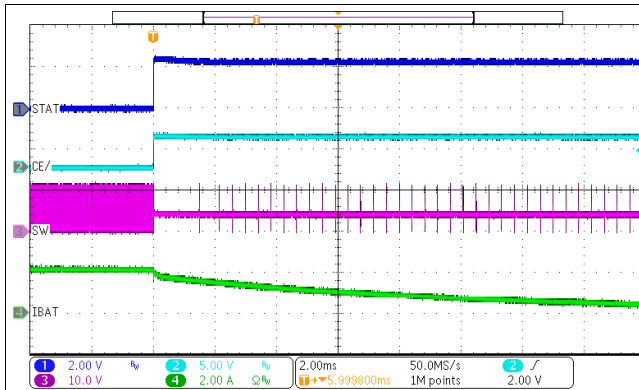
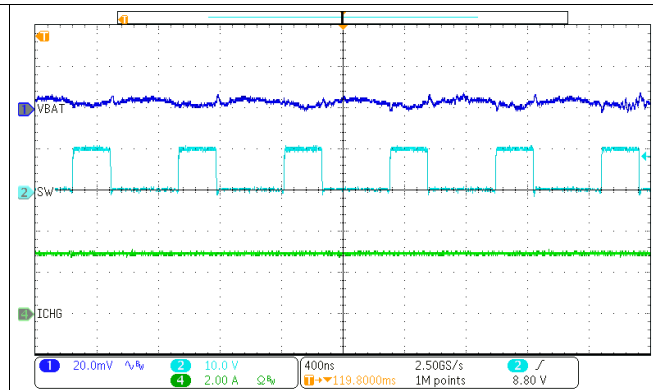


图 61. Charge Enable



VBUS = 12 V

图 62. Charge Disable

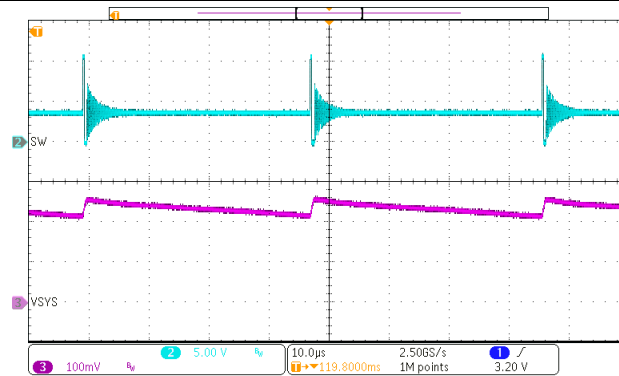


VBUS = 12 V

VBAT = 3.8 V

ICHG = 3 A

图 63. PWM Switching Waveform



VBUS = 12 V

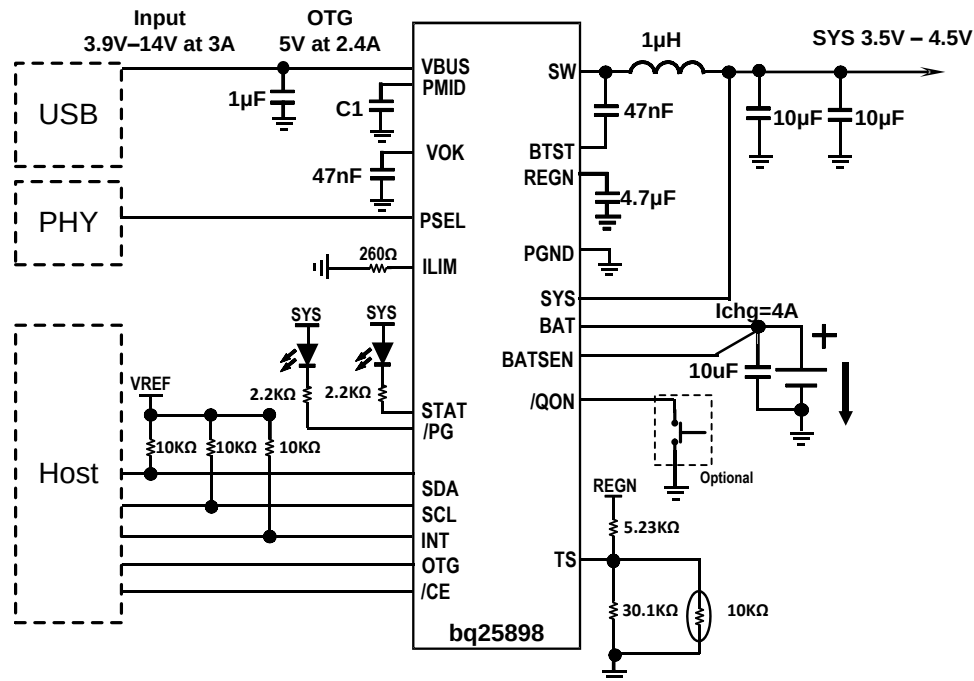
ISYS = 7 mA

Charge Disable

图 64. PFM Switching Waveform



### 10.3 System Example



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C1 = 8.2μF (OTG ≤ 1.8A) or 20μF (OTG ≤ 2.4A) is recommended

**图 65. bq25898 with PSEL Interface and USB On-The-Go (OTG)**

## 11 Power Supply Recommendations

In order to provide an output voltage on SYS, the device requires a power supply between 3.9 V and 14 V input with at least 100-mA current rating connected to VBUS or a single-cell Li-Ion battery with voltage  $> V_{BATUVLO}$  connected to BAT. The source current rating needs to be at least 3 A in order for the buck converter of the charger to provide maximum output power to SYS.

## 12 Layout

### 12.1 Layout Guidelines

The switching node rise and fall times should be minimized for minimum switching loss. Proper layout of the components to minimize high frequency current path loop (see 图 66) is important to prevent electrical and magnetic field radiation and high frequency resonant problems. Here is a PCB layout priority list for proper layout. Layout PCB according to this specific order is essential.

1. Place input capacitor as close as possible to PMID pin and GND pin connections and use shortest copper trace connection or GND plane.
2. Put output capacitor near to the inductor and the IC.
3. Decoupling capacitors should be placed next to the IC pins and make trace connection as short as possible.
4. Place inductor input terminal to SW pin as close as possible. Minimize the copper area of this trace to lower electrical and magnetic field radiation but make the trace wide enough to carry the charging current. Do not use multiple layers in parallel for this connection. Minimize parasitic capacitance from this area to any other trace or plane.
5. Connect all grounds together to reduce PCB size and improve thermal dissipation.
6. Avoid ground planes in parallel with high frequency traces in other layers.

### 12.2 Layout Example

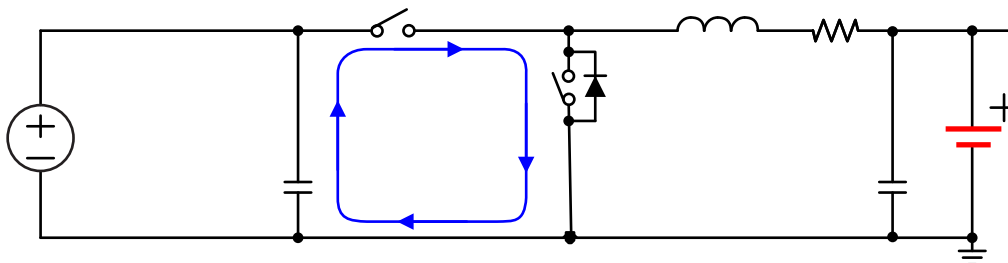


图 66. High Frequency Current Path

## 13 器件和文档支持

### 13.1 器件支持

#### 13.1.1 Third-Party Products Disclaimer

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### 13.2 相关链接

下面的表格列出了快速访问链接。类别包括技术文档、支持与社区资源、工具和软件，以及申请样片或购买产品的快速链接。

表 31. 相关链接

| 器件       | 产品文件夹                 | 立即订购                  | 技术文档                  | 工具和软件                 | 支持和社区                 |
|----------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|
| bq25898  | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |
| bq25898D | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |

### 13.3 接收文档更新通知

要接收文档更新通知，请导航至 [TI.com](#) 上的器件产品文件夹。请单击右上角的通知我 进行注册，即可收到任意产品信息更改每周摘要。有关更改的详细信息，请查看任意已修订文档中包含的修订历史记录。

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下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

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**设计支持** *TI 参考设计支持* 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

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### 13.7 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 14 机械、封装和可订购信息

以下页面包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据发生变化时，我们可能不会另行通知或修订此文档。如欲获取此产品说明书的浏览器版本，请参见左侧的导航栏。

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">BQ25898DYFFR</a> | Active        | Production           | DSBGA (YFF)   42 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898D            |
| BQ25898DYFFR.A               | Active        | Production           | DSBGA (YFF)   42 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898D            |
| <a href="#">BQ25898DYFFT</a> | Active        | Production           | DSBGA (YFF)   42 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898D            |
| BQ25898DYFFT.A               | Active        | Production           | DSBGA (YFF)   42 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898D            |
| <a href="#">BQ25898YFFR</a>  | Active        | Production           | DSBGA (YFF)   42 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898             |
| BQ25898YFFR.A                | Active        | Production           | DSBGA (YFF)   42 | 3000   LARGE T&R      | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898             |
| <a href="#">BQ25898YFFT</a>  | Active        | Production           | DSBGA (YFF)   42 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898             |
| BQ25898YFFT.A                | Active        | Production           | DSBGA (YFF)   42 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 125   | BQ25898             |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

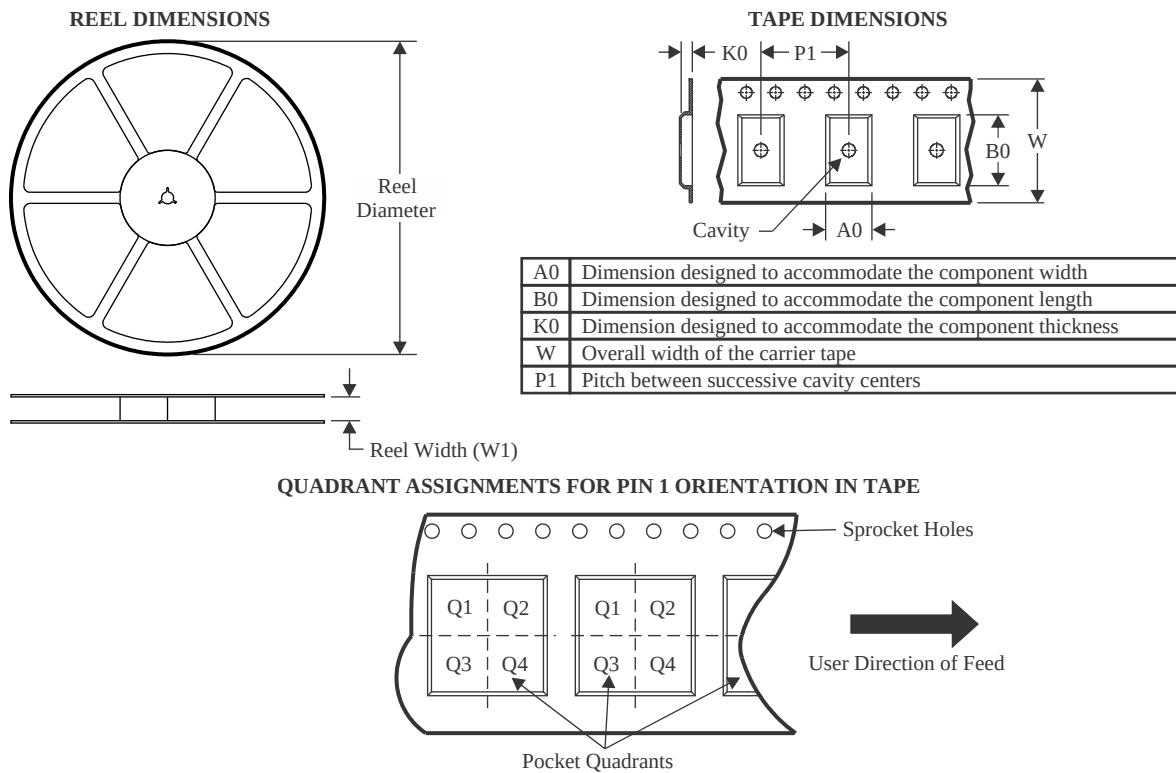
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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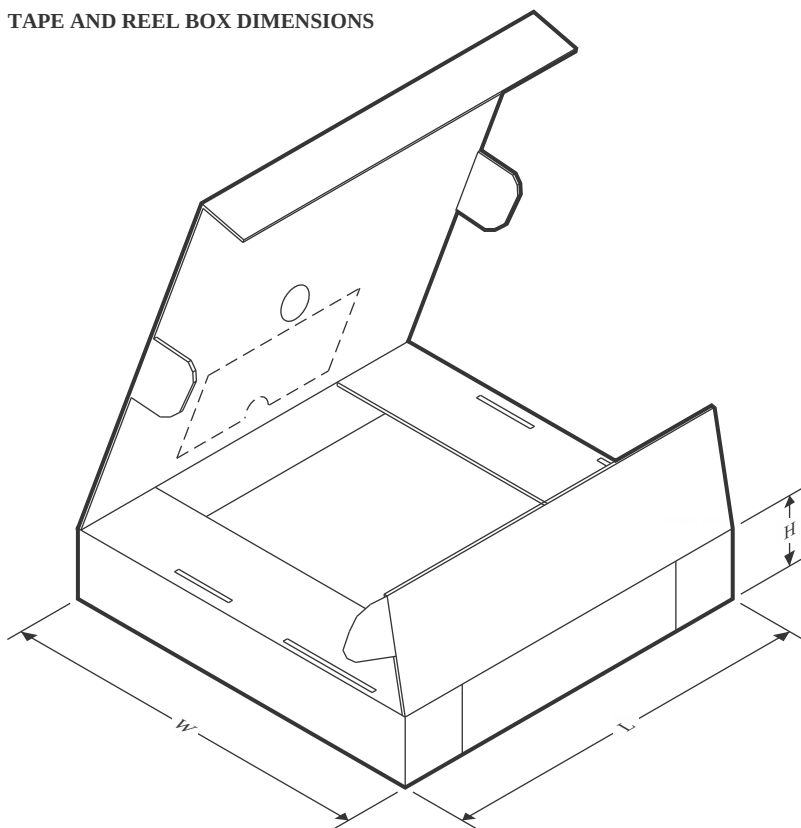
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| BQ25898DYFFR | DSBGA        | YFF             | 42   | 3000 | 180.0              | 8.4                | 2.66    | 2.95    | 0.81    | 4.0     | 8.0    | Q1            |
| BQ25898DYFFT | DSBGA        | YFF             | 42   | 250  | 180.0              | 8.4                | 2.66    | 2.95    | 0.81    | 4.0     | 8.0    | Q1            |
| BQ25898YFFR  | DSBGA        | YFF             | 42   | 3000 | 180.0              | 8.4                | 2.66    | 2.95    | 0.81    | 4.0     | 8.0    | Q1            |
| BQ25898YFFR  | DSBGA        | YFF             | 42   | 3000 | 180.0              | 8.4                | 2.66    | 2.95    | 0.81    | 4.0     | 8.0    | Q1            |
| BQ25898YFFT  | DSBGA        | YFF             | 42   | 250  | 180.0              | 8.4                | 2.66    | 2.95    | 0.81    | 4.0     | 8.0    | Q1            |

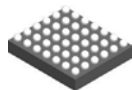
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ25898DYFFR | DSBGA        | YFF             | 42   | 3000 | 182.0       | 182.0      | 20.0        |
| BQ25898DYFFT | DSBGA        | YFF             | 42   | 250  | 182.0       | 182.0      | 20.0        |
| BQ25898YFFR  | DSBGA        | YFF             | 42   | 3000 | 182.0       | 182.0      | 20.0        |
| BQ25898YFFR  | DSBGA        | YFF             | 42   | 3000 | 182.0       | 182.0      | 20.0        |
| BQ25898YFFT  | DSBGA        | YFF             | 42   | 250  | 182.0       | 182.0      | 20.0        |

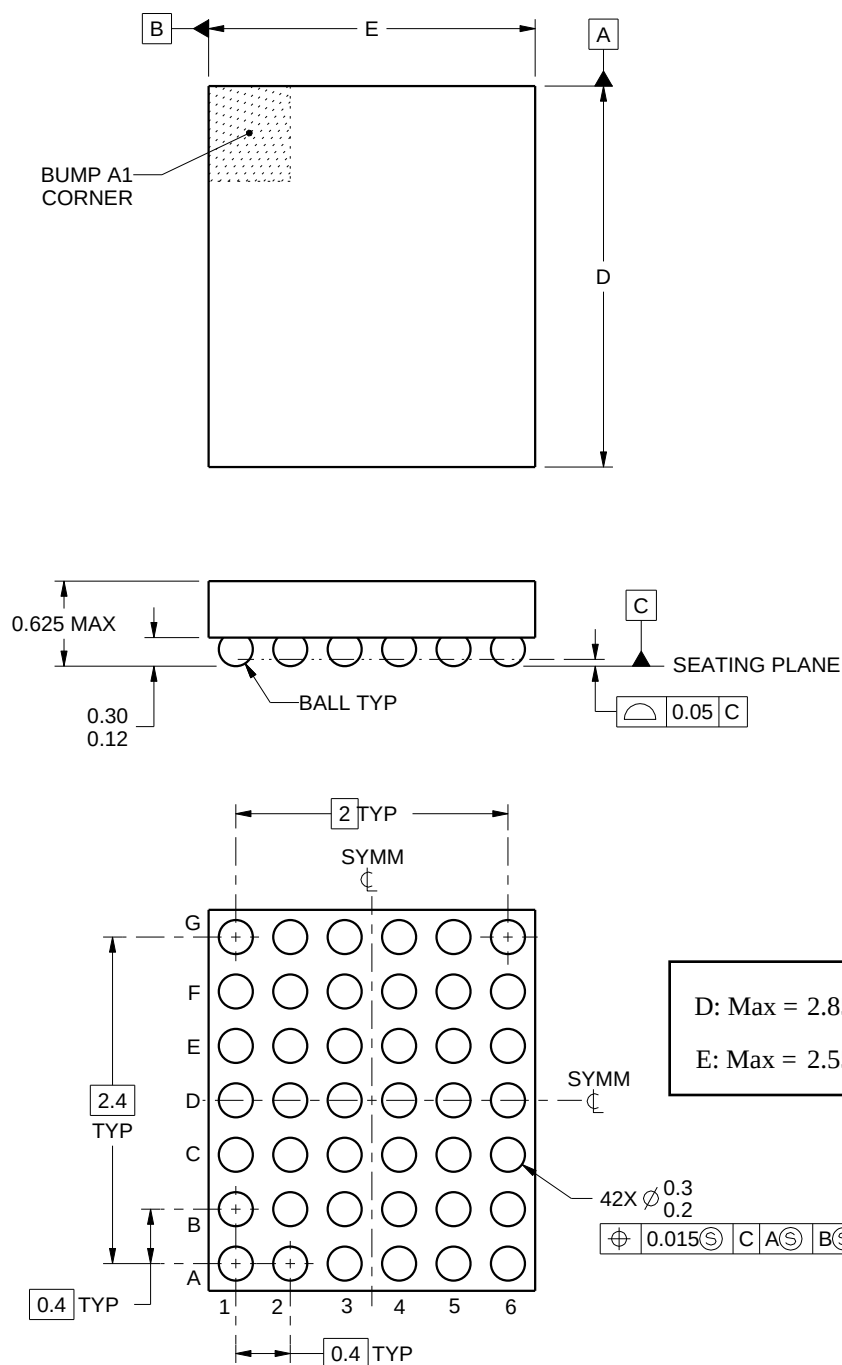
YFF0042



# PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



4222067/A 05/2015

## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

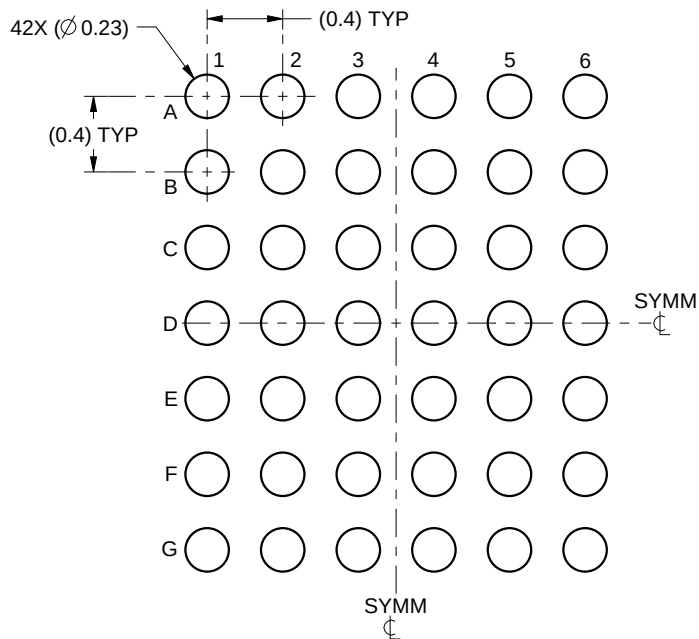


# EXAMPLE BOARD LAYOUT

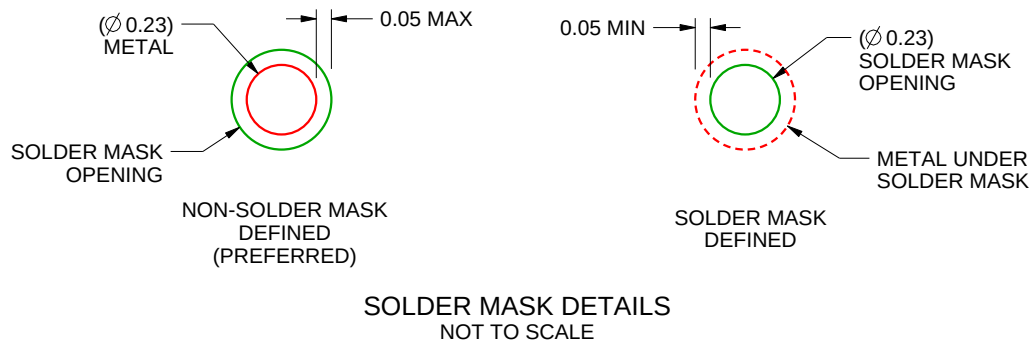
YFF0042

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
SCALE:25X



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NOTES: (continued)

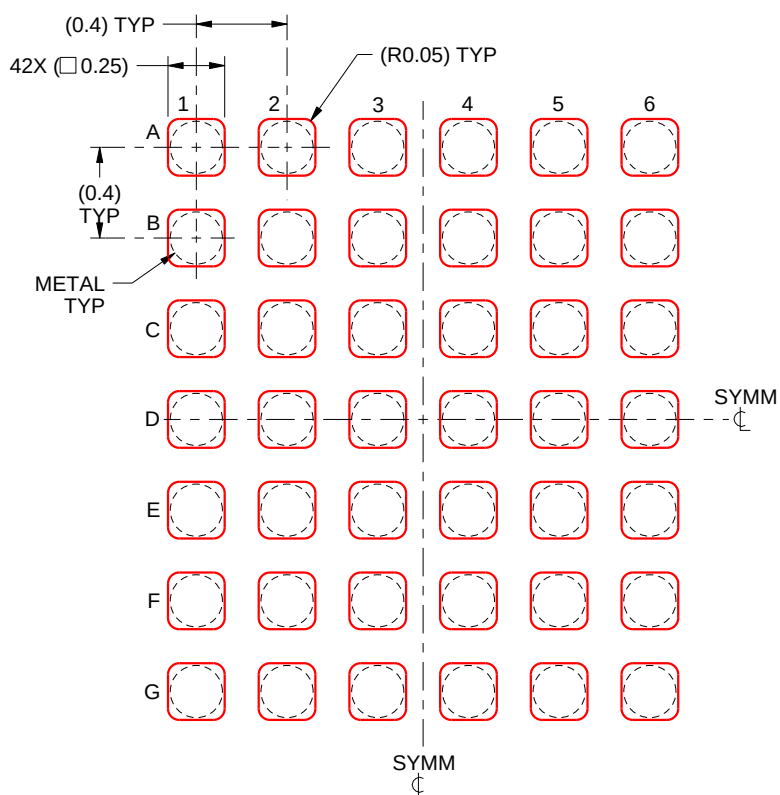
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

# EXAMPLE STENCIL DESIGN

YFF0042

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X

4222067/A 05/2015

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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